

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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- High Slew Rate . . . 10.5 V/ μ s Typ
- High-Gain Bandwidth . . . 5.1 MHz Typ
- Supply Voltage Range 2.5 V to 5.5 V
- Rail-to-Rail Output
- 360 μ V Input Offset Voltage
- Low Distortion Driving 600- Ω
0.005% THD+N
- 1 mA Supply Current (Per Channel)
- 17 nV/ $\sqrt{\text{Hz}}$ Input Noise Voltage
- 2 pA Input Bias Current
- Characterized From $T_A = -55^\circ\text{C}$ to 125°C
- Available in MSOP and SOT-23 Packages
- Micropower Shutdown Mode . . . $I_{DD} < 1 \mu\text{A}$
- Available in Q-Temp Automotive
High Reliability Automotive Applications
Configuration Control / Print Support
Qualification to Automotive Standards

description

The TLV277x CMOS operational amplifier family combines high slew rate and bandwidth, rail-to-rail output swing, high output drive, and excellent dc precision. The device provides 10.5 V/ μ s of slew rate and 5.1 MHz of bandwidth while only consuming 1 mA of supply current per channel. This ac performance is much higher than current competitive CMOS amplifiers. The rail-to-rail output swing and high output drive make these devices a good choice for driving the analog input or reference of analog-to-digital converters. These devices also have low distortion while driving a 600- Ω load for use in telecom systems.

These amplifiers have a 360- μ V input offset voltage, a 17 nV/ $\sqrt{\text{Hz}}$ input noise voltage, and a 2-pA input bias current for measurement, medical, and industrial applications. The TLV277x family is also specified across an extended temperature range (-40°C to 125°C), making it useful for automotive systems, and the military temperature range (-55°C to 125°C), for military systems.

These devices operate from a 2.5-V to 5.5-V single supply voltage and are characterized at 2.7 V and 5 V. The single-supply operation and low power consumption make these devices a good solution for portable applications. The following table lists the packages available.

FAMILY PACKAGE TABLE

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES								SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	CDIP	SOIC	SOT-23	TSSOP	MSOP	LCCC	CPAK		
TLV2770	1	8	—	8	—	—	8	—	—	Yes	Refer to the EVM Selection Guide (Lit# SLOU060)
TLV2771	1	—	—	8	5	—	—	—	—	—	
TLV2772	2	8	8	8	—	8	8	20	10	—	
TLV2773	2	14	—	14	—	—	10	—	—	Yes	
TLV2774	4	14	—	14	—	14	—	—	—	—	
TLV2775	4	16	—	16	—	16	—	—	—	Yes	

A SELECTION OF SINGLE-SUPPLY OPERATIONAL AMPLIFIER PRODUCTS[†]

DEVICE	V _{DD} (V)	BW (MHz)	SLEW RATE (V/ μ s)	I _{DD} (per channel) (μ A)	RAIL-TO-RAIL
TLV277X	2.5 – 6.0	5.1	10.5	1000	O
TLV247X	2.7 – 6.0	2.8	1.5	600	I/O
TLV245X	2.7 – 6.0	0.22	0.11	23	I/O
TLV246X	2.7 – 6.0	6.4	1.6	550	I/O

[†] All specifications measured at 5 V.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

This document contains information on products in more than one phase of development. The status of each device is indicated on the page(s) specifying its electrical characteristics.

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On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.

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TLV2770 and TLV2771 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C (mV)	PACKAGED DEVICES			
		SMALL OUTLINE (D)	SOT-23 (DBV)	MSOP (DGK)	PLASTIC DIP (P)
0°C to 70°C	2.5	TLV2770CD TLV2771CD	— TLV2771CDBV	TLV2770CDGK† —	TLV2770CP —
–40°C to 125°C	2.5	TLV2770ID TLV2771ID	— TLV2771IDBV	TLV2770IDGK† —	TLV2770IP —
	1.6	TLV2770AID TLV2771AID	— —	— —	TLV2770AIP —

† This device is in the Product Preview stage of development. Please contact your local TI sales office for availability.

TLV2772 and TLV2773 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C (mV)	PACKAGED DEVICES				
		SMALL OUTLINE (D)	MSOP (DGK)	MSOP (DGS)	PLASTIC DIP (N)	PLASTIC DIP (P)
0°C to 70°C	2.5	TLV2772CD TLV2773CD	TLV2772CDGK —	— TLV2773CDGS	— TLV2773CN	TLV2772CP —
–40°C to 125°C	2.5	TLV2772ID TLV2773ID	TLV2772IDGK —	— TLV2773IDGS	— TLV2773IN	TLV2772IP —
	1.6	TLV2772AID TLV2773AID	— —	— —	— TLV2773AIN	TLV2772AIP —

TLV2774 and TLV2775 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C (mV)	PACKAGED DEVICES			
		SMALL OUTLINE (D)	PLASTIC DIP (N)	PLASTIC DIP (P)	TSSOP (PW)
0°C to 70°C	2.7	TLV2774CD TLV2775CD	— TLV2775CN	TLV2774CP —	TLV2774CPW TLV2775CPW
–40°C to 125°C	2.7	TLV2774ID TLV2775ID	— TLV2775IN	TLV2774IP —	TLV2774IPW TLV2775IPW
	2.1	TLV2774AID TLV2775AID	— TLV2775AIN	TLV2774AIP —	TLV2774AIPW TLV2775AIPW

TLV2772M/Q AND TLV2772AM/Q AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C (mV)	PACKAGED DEVICES				
		SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	CERAMIC FLATPACK (U)	TSSOP (PW)
–40°C to 125°C	2.5	TLV2772QD‡	—	—	—	TLV2772QPW‡
	1.6	TLV2772AQD‡	—	—	—	TLV2772AQPW‡
–55°C to 125°C	2.5	TLV2772MD	TLV2772MFK	TLV2772MJG	TLV2772MU	—
	1.6	TLV2772AMD	TLV2772AMFK	TLV2772AMJG	TLV2772AMU	—

‡ Available in tape and reel

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PACKAGE TYPE	PINS	PART NUMBER	SYMBOL†
SOT23	5 Pin	TLV2771CDBV	VAMC
		TLV2771IDBV	VAMI
MSOP	8 Pin	TLV2770CDGK	xxTIABO
		TLV2770IDGK	xxTIABP
		TLV2772CDGK	xxTIAAF
		TLV2772IDGK	xxTIAAG
	10 Pin	TLV2773CDGS	xxTIABQ
		TLV2773IDGS	xxTIABR

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TLV277x PACKAGE PINOUTS⁽¹⁾



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(1) SOT-23 may or may not be indicated

TYPICAL PIN 1 INDICATORS



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{DD} (see Note 1)	7 V
Differential input voltage, V_{ID} (see Note 2)	$\pm V_{DD}$
Input voltage range, V_I (any input, see Note 1)	-0.3 V to V_{DD}
Input current, I_I (any input)	± 4 mA
Output current, I_O	± 50 mA
Total current into V_{DD+}	± 50 mA
Total current out of GND	± 50 mA
Duration of short-circuit current (at or below) 25°C (see Note 3)	unlimited
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	-40°C to 125°C
Q suffix	-40°C to 125°C
M suffix	-55°C to 125°C
Storage temperature range, T_{stg}	-65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential voltages, are with respect to GND.
 2. Differential voltages are at the noninverting input with respect to the inverting input. Excessive current flows when input is brought below GND - 0.3 V.
 3. The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
DBV	437 mW	3.5 mW/°C	280 mW	227 mW	87 mW
DGK	424 mW	3.4 mW/°C	271 mW	220 mW	85 mW
DGS	424 mW	3.4 mW/°C	271 mW	220 mW	85 mW
FK	1375 mW	11.0 mW/°C	672 mW	546 mW	210 mW
JG	1050 mW	8.4 mW/°C	880 mW	714 mW	275 mW
N	1150 mW	9.2 mW/°C	736 mW	598 mW	230 mW
P	1000 mW	8.0 mW/°C	640 mW	520 mW	200 mW
PW	700 mW	5.6 mW/°C	448 mW	364 mW	140 mW
U	675 mW	5.4 mW/°C	432 mW	350 mW	135 mW

recommended operating conditions

	C SUFFIX		I SUFFIX		Q SUFFIX		M SUFFIX		UNIT
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
Supply voltage, V_{DD}	2.5	6	2.5	6	2.5	6	2.5	6	V
Input voltage range, V_I	GND	$V_{DD+} - 1.3$	GND	$V_{DD+} - 1.3$	GND	$V_{DD+} - 1.3$	GND	$V_{DD+} - 1.3$	V
Common-mode input voltage, V_{IC}	GND	$V_{DD+} - 1.3$	GND	$V_{DD+} - 1.3$	GND	$V_{DD+} - 1.3$	GND	$V_{DD+} - 1.3$	V
Operating free-air temperature, T_A	0	70	-40	125	-40	125	-55	125	°C

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electrical characteristics at specified free-air temperature, $V_{DD} = 2.7$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A^\dagger$	TLV277xC			UNIT
				MIN	TYP	MAX	
V_{IO}	Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$, No load	$V_O = 0$, $V_{DD} = \pm 1.35$ V	25°C	0.48	2.5	mV
				Full range	0.53	2.7	
				25°C	0.8	2.7	
				Full range	0.86	2.9	
α_{VIO}	Temperature coefficient of input offset voltage		25°C to 125°C		2		$\mu V/^\circ C$
I_{IO}	Input offset current	$V_{IC} = 0$, $R_S = 50\ \Omega$	$V_O = 0$, $V_{DD} = \pm 1.35$ V	25°C	1	60	pA
				Full range	2	100	
I_{IB}	Input bias current			25°C	2	60	pA
				Full range	6	100	
V_{OH}	High-level output voltage	$I_{OH} = -0.675$ mA		25°C	2.6		V
				Full range	2.5		
		$I_{OH} = -2.2$ mA		25°C	2.4		
				Full range	2.1		
V_{OL}	Low-level output voltage	$V_{IC} = 1.35$ V, $I_{OL} = 0.675$ mA		25°C	0.1		V
				Full range	0.2		
		$V_{IC} = 1.35$ V, $I_{OL} = 2.2$ mA		25°C	0.21		
				Full range	0.6		
A_{VD}	Large-signal differential voltage amplification	$V_{IC} = 1.35$ V, $V_O = 0.6$ V to 2.1 V	$R_L = 10$ k Ω ,	25°C	20	380	V/mV
				Full range	13		
$r_{i(d)}$	Differential input resistance			25°C	10 ¹²		Ω
$c_{i(c)}$	Common-mode input capacitance	$f = 10$ kHz		25°C	8		pF
z_o	Closed-loop output impedance	$f = 100$ kHz, $A_V = 10$		25°C	25		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = 0$ to 1.5 V, $R_S = 50\ \Omega$	$V_O = V_{DD}/2$,	25°C	60	84	dB
				Full range	60	82	
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	$V_{DD} = 2.7$ V to 5 V, No load	$V_{IC} = V_{DD}/2$,	25°C	70	89	dB
				Full range	70	84	
I_{DD}	Supply current (per channel)	$V_O = V_{DD}/2$, No load		25°C	1	2	mA
				Full range		2	
$I_{DD(SHDN)}$	Supply current in shutdown (per channel)			25°C	0.8	1.5	μA
				Full range	1.3	2	
$V_{(ON)}$	Turnon voltage level	TLV2770	$A_V = 5$	25°C	1.47		V
		TLV2773			1.43		
		TLV2775			1.40		
$V_{(OFF)}$	Turnoff voltage level	TLV2770	$A_V = 5$	25°C	1.27		V
		TLV2773			1.21		
		TLV2775			1.20		

[†] Full range is 0°C to 70°C.

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operating characteristics at specified free-air temperature, $V_{DD} = 2.7\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLV277xC			UNIT
					MIN	TYP	MAX	
SR	Slew rate at unity gain	V _{O(PP)} = 0.8 V, C _L = 100 pF, R _L = 10 kΩ		25°C	5	9	V/μs	
				Full range	4.7	6		
V _n	Equivalent input noise voltage	f = 1 kHz		25°C	21		nV/√Hz	
		f = 10 kHz		25°C	17			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	0.33		μV	
		f = 0.1 Hz to 10 Hz			0.86			
I _n	Equivalent input noise current	f = 100 Hz		25°C	0.6		fA/√Hz	
THD + N	Total harmonic distortion plus noise	R _L = 600 Ω, f = 1 kHz	A _V = 1	25°C	0.0085%			
			A _V = 10		0.025%			
			A _V = 100		0.12%			
Gain-bandwidth product		f = 10 kHz, C _L = 100 pF	R _L = 600 Ω,	25°C	4.8		MHz	
t _s	Settling time	A _V = −1, Step = 1 V, R _L = 600 Ω, C _L = 100 pF	0.1%	25°C	0.186		μs	
			0.01%	25°C	0.3			
φ _m	Phase margin at unity gain	R _L = 600 Ω, C _L = 100 pF		25°C	46°			
	Gain margin			25°C	12		dB	

† Full range is 0°C to 70°C.

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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T _A [†]	TLV277xC			UNIT	
				MIN	TYP	MAX		
V _{IO}	Input offset voltage	TLV2770/1/2 TLV2773/4/5	V _{IC} = 0, R _S = 50 Ω, No load	V _O = 0, V _{DD} = ±2.5 V,	25°C	0.5	2.5	mV
					Full range	0.6	2.7	
					25°C	0.7	2.5	
					Full range	0.78	2.7	
α _{VIO}	Temperature coefficient of input offset voltage	V _{IC} = 0, R _S = 50 Ω	V _O = 0, V _{DD} = ±2.5 V	25°C to 125°C	2		μV/°C	
I _{IO}	Input offset current			25°C	1	60	pA	
				Full range	2	100		
I _{IB}	Input bias current			25°C	2	60	pA	
				Full range	6	100		
V _{OH}	High-level output voltage			I _{OH} = −1.3 mA	25°C	4.9		V
					Full range	4.8		
				I _{OH} = −4.2 mA	25°C	4.7		
		Full range	4.4					
V _{OL}	Low-level output voltage	V _{IC} = 2.5 V, I _{OL} = 1.3 mA	25°C	0.1		V		
			Full range	0.2				
		V _{IC} = 2.5 V, I _{OL} = 4.2 mA	25°C	0.21				
			Full range	0.6				
A _{VD}	Large-signal differential voltage amplification	V _{IC} = 2.5 V, V _O = 1 V to 4 V	R _L = 10 kΩ,	25°C	20	450	V/mV	
				Full range	13			
r _{i(d)}	Differential input resistance			25°C	10 ¹²		Ω	
c _{i(c)}	Common-mode input capacitance	f = 10 kHz		25°C	8		pF	
z _O	Closed-loop output impedance	f = 100 kHz,	A _V = 10	25°C	20		Ω	
CMRR	Common-mode rejection ratio	V _{IC} = 0 to 3.7 V, R _S = 50 Ω	V _O = V _{DD} /2,	25°C	70	96	dB	
				Full range	70	93		
k _{SVR}	Supply voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 2.7 V to 5 V, No load	V _{IC} = V _{DD} /2,	25°C	70	89	dB	
				Full range	70	84		
I _{DD}	Supply current (per channel)	V _O = V _{DD} /2,	No load	25°C	1	2	mA	
				Full range	2			
I _{DD} (SHDN)	Supply current in shutdown (per channel)			25°C	0.8	1.5	μA	
				Full range	1.3	2		
V _(ON)	Turnon voltage level	TLV2770	A _V = 5	25°C	2.59		V	
		TLV2773			2.47			
		TLV2775			2.48			
V _(OFF)	Turnoff voltage level	TLV2770	A _V = 5	25°C	2.41		V	
		TLV2773			2.32			
		TLV2775			2.29			

[†] Full range is 0°C to 70°C.

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PARAMETER			TEST CONDITIONS		T _A [†]	TLV277xC			UNIT
						MIN	TYP	MAX	
SR	Slew rate at unity gain		V _{O(PP)} = 2 V, R _L = 10 kΩ		C _L = 100 pF,	25°C	5	10.5	V/μs
						Full range	4.7	6	
V _n	Equivalent input noise voltage		f = 1 kHz			25°C	17		nV/√Hz
			f = 10 kHz			25°C	12		
V _{N(PP)}	Peak-to-peak equivalent input noise voltage		f = 0.1 Hz to 1 Hz			25°C	0.33		μV
			f = 0.1 Hz to 10 Hz				0.86		
I _n	Equivalent input noise current		f = 100 Hz			25°C	0.6		fA/√Hz
THD + N	Total harmonic distortion plus noise		R _L = 600 Ω, f = 1 kHz	A _V = 1		25°C	0.005%		
				A _V = 10			0.016%		
				A _V = 100			0.095%		
Gain-bandwidth product			f = 10 kHz, C _L = 100 pF		R _L = 600 Ω,	25°C	5.1		MHz
t _s	Settling time		A _V = -1, Step = 2 V, R _L = 600 Ω, C _L = 100 pF		0.1%	25°C	0.335		μs
					0.01%	25°C	0.6		
φ _m	Phase margin at unity gain		R _L = 600 Ω, C _L = 100 pF			25°C	46°		
Gain margin						25°C	12		dB
t _(ON)	Amplifier turnon time		TLV2770	A _V = 5, R _L = Open, Measured to 50% point		25°C	1.2		μs
			TLV2773				2.4		
			TLV2775				1.9		
t _(OFF)	Amplifier turnoff time		TLV2770	A _V = 5 R _L = Open, Measured to 50% point		25°C	335		ns
			TLV2773				444		
			TLV2775				345		

† Full range is 0°C to 70°C.

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electrical characteristics at specified free-air temperature, $V_{DD} = 2.7\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A^\dagger$	TLV277xI			TLV277xAI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO}	Input offset voltage	TLV2770/1/2 $V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega$	25°C	0.48	2.5		0.48	1.6		mV
			Full range	0.53	2.7		0.53	1.9		
	TLV2773/4/5	$V_{DD} = \pm 1.35\text{ V},$ No load	25°C	0.8	2.7		0.8	2.1		
			Full range	0.86	2.9		0.86	2.2		
α_{VIO}	Temperature coefficient of input offset voltage		25°C to 125°C	2			2			$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current	$V_{IC} = 0, V_O = 0,$ $R_S = 50\ \Omega$	25°C	1	60		1	60		pA
			Full range	2	125		2	125		
I_{IB}	Input bias current		25°C	2	60		2	60		pA
			Full range	6	350		6	350		
V_{OH}	High-level output voltage	$I_{OH} = -0.675\text{ mA}$	25°C	2.6			2.6			V
			Full range	2.5			2.5			
		$I_{OH} = -2.2\text{ mA}$	25°C	2.4			2.4			
			Full range	2.1			2.1			
V_{OL}	Low-level output voltage	$V_{IC} = 1.35\text{ V},$ $I_{OL} = 0.675\text{ mA}$	25°C	0.1			0.1			V
			Full range	0.2			0.2			
		$V_{IC} = 1.35\text{ V},$ $I_{OL} = 2.2\text{ mA}$	25°C	0.21			0.21			
			Full range	0.6			0.6			
A_{VD}	Large-signal differential voltage amplification	$V_{IC} = 1.35\text{ V},$ $R_L = 10\text{ k}\Omega,$ $V_O = 0.6\text{ V to } 2.1\text{ V}$	25°C	20	380		20	380		V/mV
			Full range	13			13			
$r_{i(d)}$	Differential input resistance		25°C	10 ¹²			10 ¹²			Ω
$c_{i(c)}$	Common-mode input capacitance	$f = 10\text{ kHz},$	25°C	8			8			pF
z_o	Closed-loop output impedance	$f = 100\text{ kHz},$ $A_V = 10$	25°C	25			25			Ω
CMRR	Common-mode rejection ratio	$V_{IC} = 0\text{ to } 1.5\text{ V},$ $V_O = V_{DD}/2,$ $R_S = 50\ \Omega$	25°C	60	84		60	84		dB
			Full range	60	82		60	82		
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to } 5\text{ V},$ $V_{IC} = V_{DD}/2,$ No load	25°C	70	89		70	89		dB
			Full range	70	84		70	84		
I_{DD}	Supply current (per channel)	$V_O = V_{DD}/2,$ No load	25°C	1	2		1	2		mA
			Full range		2			2		
$I_{DD(SHDN)}$	Supply current in shutdown (per channel)		25°C	0.8	1.5		0.8	1.5		μA
			Full range	1.3	2		1.3	2		

[†] Full range is -40°C to 125°C .

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electrical characteristics at specified free-air temperature, $V_{DD} = 2.7$ V (unless otherwise noted)
(continued)

PARAMETER		TEST CONDITIONS	T _A [†]	TLV277xI			TLV277xAI			UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX		
V _(ON)	Turnon voltage level	TLV2770	A _V = 5	25°C	1.47			1.47			V
		TLV2773			1.43			1.43			
		TLV2775			1.40			1.4			
V _(OFF)	Turnoff voltage level	TLV2770	A _V = 5	25°C	1.27			1.27			V
		TLV2773			1.21			1.21			
		TLV2775			1.20			1.2			

† Full range is – 40°C to 125°C.

operating characteristics at specified free-air temperature, $V_{DD} = 2.7$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	TLV277xI			TLV277xAI			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V _{O(PP)} = 0.8 V, C _L = 100 pF, R _L = 10 kΩ		25°C	5	9		5	9		V/μs
				Full range	4.7	6		4.7	6		
V _n	Equivalent input noise voltage	f = 1 kHz		25°C	21			21			nV/√Hz
		f = 10 kHz		25°C	17			17			
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	0.33			0.33			μV
		f = 0.1 Hz to 10 Hz		25°C	0.86			0.86			μV
I _n	Equivalent input noise current	f = 100 Hz		25°C	0.6			0.6			fA/√Hz
THD + N	Total harmonic distortion plus noise	R _L = 600 Ω, f = 1 kHz	A _V = 1	25°C	0.0085%			0.0085%			
			A _V = 10		0.025%			0.025%			
			A _V = 100		0.12%			0.12%			
Gain-bandwidth product		f = 10 kHz, R _L = 600 Ω, C _L = 100 pF		25°C	4.8			4.8			MHz
t _s	Settling time	A _V = −1, Step = 0.85 V to 1.85 V, R _L = 600 Ω, C _L = 100 pF	0.1%	25°C	0.186			0.186			μs
			0.01%	25°C	3.92			3.92			
φ _m	Phase margin at unity gain	R _L = 600 Ω, C _L = 100 pF		25°C	46°			46°			
Gain margin				25°C	12			12			dB

† Full range is – 40°C to 125°C.

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PARAMETER		TEST CONDITIONS	T _A [†]	TLV277xI			TLV277xAI			UNIT
				MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO}	Input offset voltage	V _{IC} = 0, No load V _O = 0, R _S = 50 Ω, V _{DD} = ±2.5 V	25°C	0.5 2.5		0.5 1.6		mV		
			Full range	0.6 2.7		0.6 1.9				
			25°C	0.7 2.5		0.7 2.1				
			Full range	0.78 2.7		0.78 2.2				
α _{VIO}	Temperature coefficient of input offset voltage	V _{IC} = 0, V _O = 0, R _S = 50 Ω, V _{DD} = ±2.5 V	25°C to 125°C	2		2		μV/°C		
I _{IO}	Input offset current		25°C	1 60		1 60		pA		
I _{IB}	Input bias current		Full range	2 125		2 125				
			25°C	2 60		2 60		pA		
			Full range	6 350		6 350				
V _{OH}	High-level output voltage	I _{OH} = −1.3 mA	25°C	4.9		4.9		V		
			Full range	4.8		4.8				
		I _{OH} = −4.2 mA	25°C	4.7		4.7				
			Full range	4.4		4.4				
V _{OL}	Low-level output voltage	V _{IC} = 2.5 V, I _{OL} = 1.3 mA	25°C	0.1		0.1		V		
			Full range	0.2		0.2				
		V _{IC} = 2.5 V, I _{OL} = 4.2 mA	25°C	0.21		0.21				
			Full range	0.6		0.6				
A _{VD}	Large-signal differential voltage amplification	V _{IC} = 2.5 V, R _L = 10 kΩ, V _O = 1 V to 4 V	25°C	20	450	20	450	V/mV		
			Full range	13		13				
r _{i(d)}	Differential input resistance		25°C	10 ¹²			10 ¹²	Ω		
c _{i(c)}	Common-mode input capacitance	f = 10 kHz	25°C	8			8	pF		
z _o	Closed-loop output impedance	f = 100 kHz, A _V = 10	25°C	20			20	Ω		
CMRR	Common-mode rejection ratio	V _{IC} = 0 to 3.7 V, V _O = V _{DD} /2, R _S = 50 Ω	25°C	60	96	70	96	dB		
			Full range	60	93	70	93			
k _{SVR}	Supply voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 2.7 V to 5 V, V _{IC} = V _{DD} /2, No load	25°C	70	89	70	89	dB		
			Full range	70	84	70	84			
I _{DD}	Supply current (per channel)	V _O = V _{DD} /2, No load	25°C	1	2	1	2	mA		
			Full range	2		2				
I _{DD} (SHDN)	Supply current shutdown (per channel)		25°C	0.8	1.5	0.8	1.5	μA		
			Full range	1.3	2	1.3	2			

[†] Full range is -40°C to 125°C .

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(continued)

PARAMETER		TEST CONDITIONS	T _A [†]	TLV277xI			TLV277xAI			UNIT	
				MIN	TYP	MAX	MIN	TYP	MAX		
V _(ON)	Turnon voltage level	TLV2770	A _V = 5	25°C	2.59			2.59			V
		TLV2773			2.47			2.47			
		TLV2775			2.48			2.48			
V _(OFF)	Turnoff voltage level	TLV2770	A _V = 5	25°C	2.41			2.41			V
		TLV2773			2.32			2.32			
		TLV2775			2.29			2.29			

† Full range is -40°C to 125°C .

operating characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER			TEST CONDITIONS		T _A †	TLV277xI			TLV277xAI			UNIT
						MIN	TYP	MAX	MIN	TYP	MAX	
SR	Slew rate at unity gain	V _{O(PP)} = 1.5 V, C _L = 100 pF, R _L = 10 kΩ		25°C	5	10.5		5	10.5		V/μs	
				Full range	4.7	6		4.7	6			
V _n	Equivalent input noise voltage	f = 1 kHz		25°C	17			17			nV/√Hz	
		f = 10 kHz		25°C	12			12				
V _{N(PP)}	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		25°C	0.33			0.33			μV	
		f = 0.1 Hz to 10 Hz		25°C	0.86			0.86			μV	
I _n	Equivalent input noise current	f = 100 Hz		25°C	0.6			0.6			fA/√Hz	
THD + N	Total harmonic distortion plus noise	R _L = 600 Ω, f = 1 kHz	A _V = 1	25°C	0.005%			0.005%				
			A _V = 10		0.016%			0.016%				
			A _V = 100		0.095%			0.095%				
Gain-bandwidth product		f = 10 kHz, R _L = 600 Ω, C _L = 100 pF		25°C	5.1			5.1			MHz	
t _s	Settling time	A _V = −1, Step = 1.5 V to 3.5 V, R _L = 600 Ω, C _L = 100 pF	0.1%	25°C	0.134			0.134			μs	
			0.01%	25°C	1.97			1.97				
φ _m	Phase margin at unity gain	R _L = 600 Ω, C _L = 100 pF		25°C	46°			46°				
Gain margin				25°C	12			12			dB	
t _(ON)	Amplifier turnon time	TLV2770	A _V = 5, R _L = Open, Measured to 50% point		25°C	1.2			1.2			μs
		TLV2773				2.4			2.4			
		TLV2775				1.9			1.9			
t _(OFF)	Amplifier turnoff time	TLV2770	A _V = 5, R _L = Open, Measured to 50% point		25°C	335			335			ns
		TLV2773				444			444			
		TLV2775				345			345			

† Full range is -40°C to 125°C .

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electrical characteristics at specified free-air temperature, $V_{DD} = 2.7\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2772Q TLV2772M			TLV2772AQ TLV2772AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{DD} = \pm 1.35\text{ V}$, $V_{IC} = 0$, $R_S = 50\ \Omega$ $V_O = 0$	25°C		0.44	2.5		0.44	1.6	mV
		Full range		0.47	2.7		0.47	1.9	
α_{VIO} Temperature coefficient of input offset voltage		25°C to 125°C		2			2		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C		1	60		1	60	pA
		Full range		2	125		2	125	
I_{IB} Input bias current		25°C		2	60		2	60	pA
		Full range		6	350		6	350	
V_{ICR} Common-mode input voltage range	CMRR > 60 dB, $R_S = 50\ \Omega$	25°C	0 to 1.4	-0.3 to 1.7		0 to 1.4	-0.3 to 1.7		V
		Full range	0 to 1.4	-0.3 to 1.7		0 to 1.4	-0.3 to 1.7		
V_{OH} High-level output voltage	$I_{OH} = -0.675\text{ mA}$	25°C		2.6			2.6		V
		Full range		2.45			2.45		
	$I_{OH} = -2.2\text{ mA}$	25°C		2.4			2.4		
		Full range		2.1			2.1		
V_{OL} Low-level output voltage	$V_{IC} = 1.35\text{ V}$, $I_{OL} = 0.675\text{ mA}$	25°C		0.1			0.1		V
		Full range		0.2			0.2		
	$V_{IC} = 1.35\text{ V}$, $I_{OL} = 2.2\text{ mA}$	25°C		0.21			0.21		
		Full range		0.6			0.6		
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 1.35\text{ V}$, $V_O = 0.6\text{ V to } 2.1\text{ V}$ $R_L = 10\text{ k}\Omega,^\ddagger$	25°C	20	380		20	380		V/mV
		Full range	13			13			
$r_{i(d)}$ Differential input resistance		25°C		10^{12}			10^{12}		Ω
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$,	25°C		8			8		pF
z_o Closed-loop output impedance	$f = 100\text{ kHz}$, $A_V = 10$	25°C		25			25		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}(\text{min})$, $R_S = 50\ \Omega$, $V_O = 1.5\text{ V}$	25°C	60	84		60	84		dB
		Full range	60	82		60	82		
k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD} / \Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to } 5\text{ V}$, $V_{IC} = V_{DD}/2$, No load	25°C	70	89		70	89		dB
		Full range	70	84		70	84		
I_{DD} Supply current (per channel)	$V_O = 1.5\text{ V}$, No load	25°C		1	2		1	2	mA
		Full range		2			2		

† Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

‡ Referenced to 1.35 V

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operating characteristics at specified free-air temperature, $V_{DD} = 2.7\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2772Q TLV2772M			TLV2772AQ TLV2772AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_{O(PP)} = 0.8\text{ V}$, $C_L = 100\text{ pF}$, $R_L = 10\text{ k}\Omega$	25°C	5	9		5	9		V/ μs
		Full range	4.7	6		4.7	6		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$	25°C		21			21		nV/ $\sqrt{\text{Hz}}$
	$f = 10\text{ kHz}$	25°C		17			17		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C		0.33			0.33		μV
	$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		0.86			0.86		μV
I_n Equivalent input noise current	$f = 100\text{ Hz}$	25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
THD + N Total harmonic distortion plus noise	$R_L = 600\text{ }\Omega$, $f = 1\text{ kHz}$	$A_V = 1$		0.0085%			0.0085%		
		$A_V = 10$		0.025%			0.025%		
		$A_V = 100$		0.12%			0.12%		
Gain-bandwidth product	$f = 10\text{ kHz}$, $C_L = 100\text{ pF}$	$R_L = 600\text{ }\Omega$, 25°C		4.8			4.8		MHz
t_s Settling time	$A_V = -1$, Step = 0.85 V to 1.85 V, $R_L = 600\text{ }\Omega$, $C_L = 100\text{ pF}$	0.1%	25°C	0.186			0.186		μs
		0.01%	25°C	3.92			3.92		
ϕ_m Phase margin at unity gain	$R_L = 600\text{ }\Omega$, $C_L = 100\text{ pF}$	25°C		46°			46°		
Gain margin		25°C		12			12		dB

† Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

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electrical characteristics at specified free-air temperature, $V_{DD} = 5\text{ V}$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2772Q TLV2772M			TLV2772AQ TLV2772AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{DD} = \pm 2.5\text{ V}$, $V_{IC} = 0$, $V_O = 0$, $R_S = 50\ \Omega$	25°C		0.36	2.5		0.36	1.6	mV
		Full range		0.4	2.7		0.4	1.9	
α_{VIO} Temperature coefficient of input offset voltage		25°C to 125°C		2			2		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current		25°C		1	60		1	60	pA
		Full range		2	125		2	125	
I_{IB} Input bias current		25°C		2	60		2	60	pA
		Full range		6	350		6	350	
V_{ICR} Common-mode input voltage range	CMRR > 60 dB, $R_S = 50\ \Omega$	25°C	0 to 3.7	-0.3 to 3.8		0 to 3.7	-0.3 to 3.8		V
		Full range	0 to 3.7	-0.3 to 3.8		0 to 3.7	-0.3 to 3.8		
V_{OH} High-level output voltage	$I_{OH} = -1.3\text{ mA}$	25°C		4.9			4.9		V
		Full range		4.8			4.8		
	$I_{OH} = -4.2\text{ mA}$	25°C		4.7			4.7		
		Full range		4.4			4.4		
V_{OL} Low-level output voltage	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 1.3\text{ mA}$	25°C		0.1			0.1		V
		Full range		0.2			0.2		
	$V_{IC} = 2.5\text{ V}$, $I_{OL} = 4.2\text{ mA}$	25°C		0.21			0.21		
		Full range		0.6			0.6		
A_{VD} Large-signal differential voltage amplification	$V_{IC} = 2.5\text{ V}$, $V_O = 1\text{ V to }4\text{ V}$	25°C	20	450		20	450		V/mV
		Full range	13			13			
$r_{i(d)}$ Differential input resistance		25°C		10^{12}			10^{12}		Ω
$C_{i(c)}$ Common-mode input capacitance	$f = 10\text{ kHz}$	25°C		8			8		pF
z_o Closed-loop output impedance	$f = 100\text{ kHz}$, $A_V = 10$	25°C		20			20		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR}(\text{min})$, $R_S = 50\ \Omega$	25°C	60	96		60	96		dB
	$V_O = 3.7\text{ V}$	Full range	60	93		60	93		
k_{SVR} Supply voltage rejection ratio ($\Delta V_{DD}/\Delta V_{IO}$)	$V_{DD} = 2.7\text{ V to }5\text{ V}$, No load	25°C	70	89		70	89		dB
		Full range	70	84		70	84		
I_{DD} Supply current (per channel)	$V_O = 1.5\text{ V}$, No load	25°C		1	2		1	2	mA
		Full range			2			2	

† Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

‡ Referenced to 2.5 V

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PARAMETER	TEST CONDITIONS	$T_A^\dagger$	TLV2772Q TLV2772M			TLV2772AQ TLV2772AM			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
SR Slew rate at unity gain	$V_{O(PP)} = 1.5\text{ V}, \quad C_L = 100\text{ pF},$ $R_L = 10\text{ k}\Omega$	25°C	5	10.5		5	10.5		V/ μs
		Full range	4.7	6		4.7	6		
V_n Equivalent input noise voltage	$f = 1\text{ kHz}$	25°C		17			17		nV/ $\sqrt{\text{Hz}}$
	$f = 10\text{ kHz}$	25°C		12			12		
$V_{N(PP)}$ Peak-to-peak equivalent input noise voltage	$f = 0.1\text{ Hz to }1\text{ Hz}$	25°C		0.33			0.33		μV
	$f = 0.1\text{ Hz to }10\text{ Hz}$	25°C		0.86			0.86		μV
I_n Equivalent input noise current	$f = 100\text{ Hz}$	25°C		0.6			0.6		fA/ $\sqrt{\text{Hz}}$
THD + N Total harmonic distortion plus noise	$R_L = 600\text{ }\Omega,$ $f = 1\text{ kHz}$	$A_V = 1$		0.005%			0.005%		
		$A_V = 10$		0.016%			0.016%		
		$A_V = 100$		0.095%			0.095%		
	Gain-bandwidth product	$f = 10\text{ kHz}, \quad R_L = 600\text{ }\Omega,$ $C_L = 100\text{ pF}$	25°C	5.1			5.1		MHz
t_s Settling time	$A_V = -1,$ Step = 1.5 V to 3.5 V, $R_L = 600\text{ }\Omega,$ $C_L = 100\text{ pF}$	0.1%	25°C	0.134			0.134		μs
		0.01%	25°C	1.97			1.97		
ϕ_m Phase margin at unity gain	$R_L = 600\text{ }\Omega, \quad C_L = 100\text{ pF}$	25°C		46°			46°		
Gain margin		25°C		12			12		dB

[†] Full range is -40°C to 125°C for Q level part, -55°C to 125°C for M level part.

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V_O	Voltage-follower large-signal pulse response		33,34
V_O	Inverting small-signal pulse response		35,36
V_O	Inverting large-signal pulse response		37,38
V_n	Equivalent input noise voltage	vs Frequency	39,40
	Noise voltage (referred to input)	Over a 10-second period	41
THD + N	Total harmonic distortion plus noise	vs Frequency	42,43
	Gain-bandwidth product	vs Supply voltage	44
B_1	Unity-gain bandwidth	vs Load capacitance	45
ϕ_m	Phase margin	vs Load capacitance	46
	Gain margin	vs Load capacitance	47
	Amplifier with shutdown pulse turnon/off characteristics		48 – 50
	Supply current with shutdown pulse turnon/off characteristics		51 – 53
	Shutdown supply current	vs Free-air temperature	54
	Shutdown forward/reverse isolation	vs Frequency	55, 56

TLV277x, TLV277xA FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 1



Figure 2



Figure 3

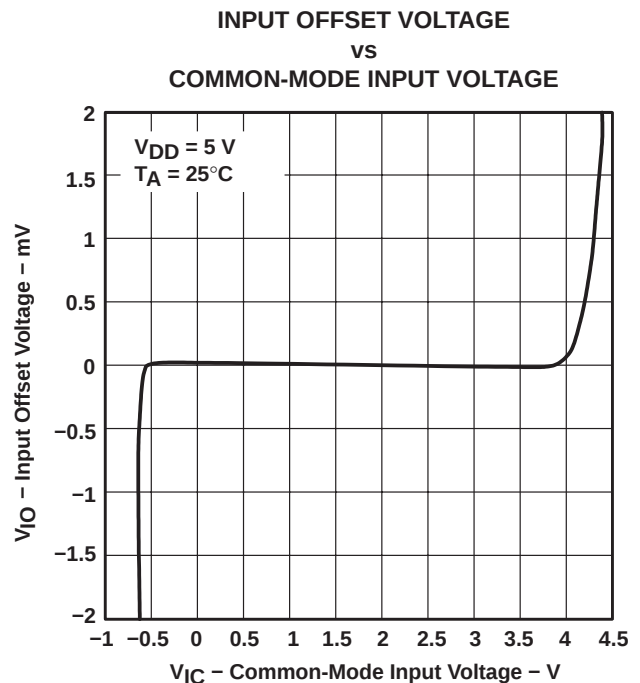


Figure 4

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 5

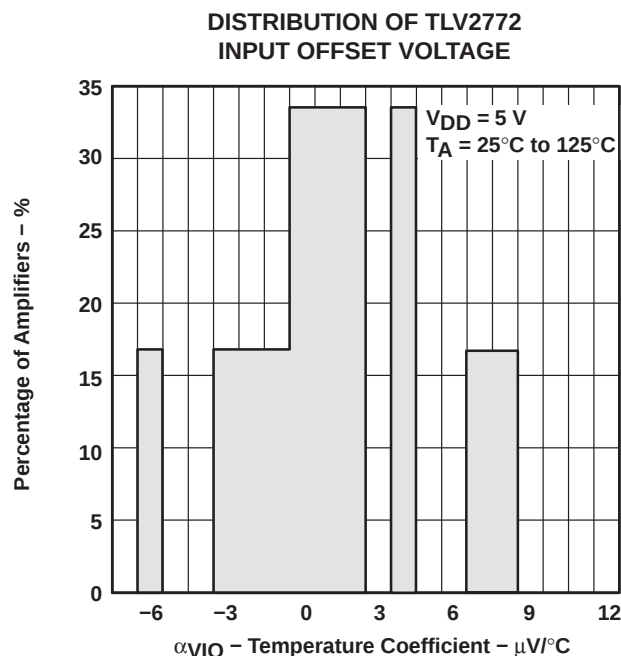


Figure 6

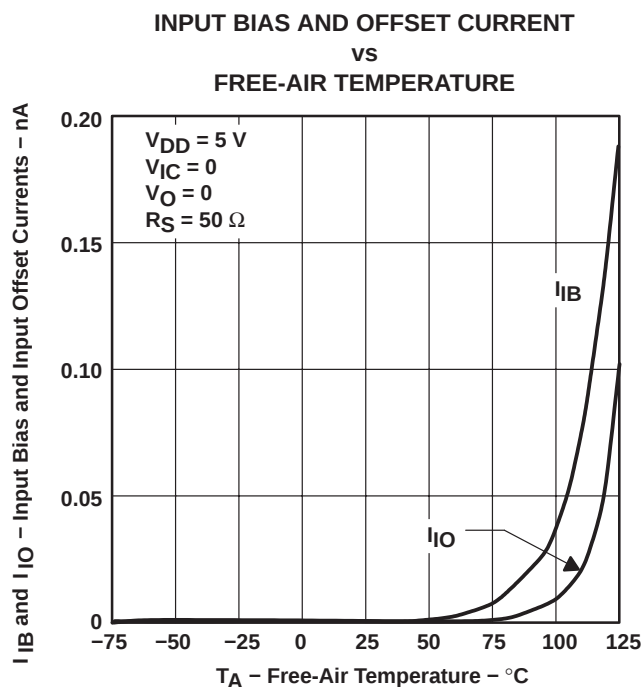


Figure 7

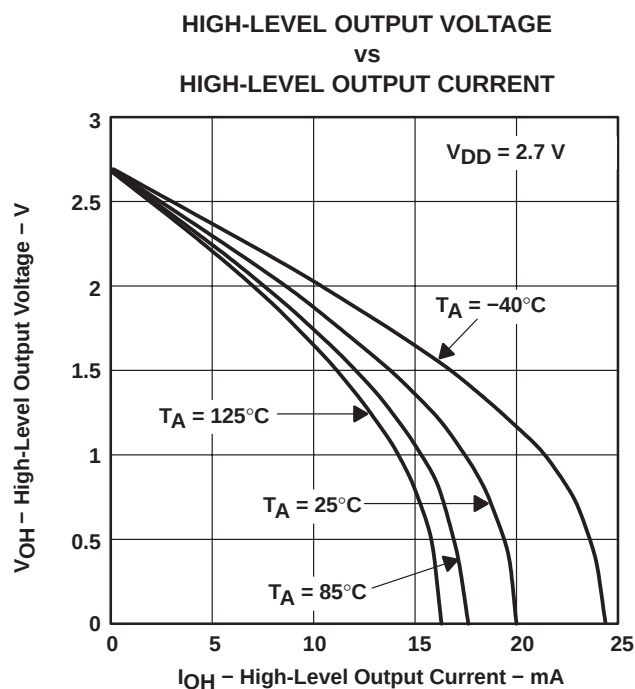


Figure 8

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 9

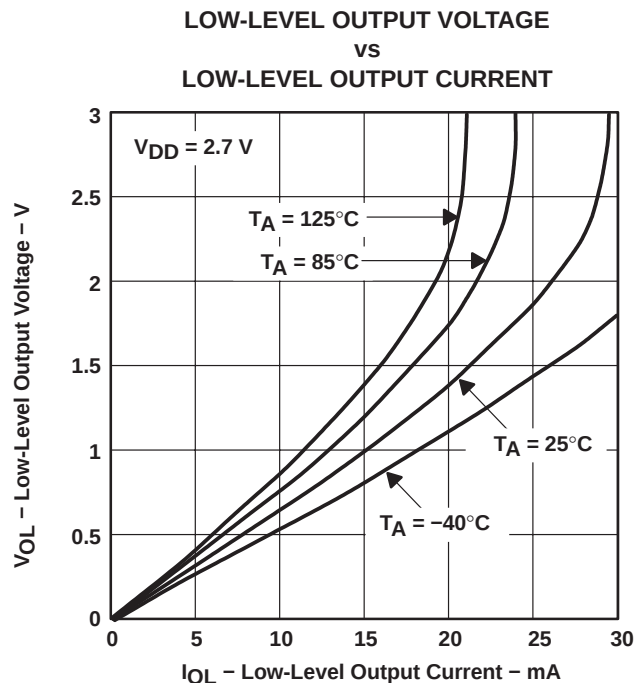


Figure 10



Figure 11



Figure 12

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 13



Figure 14



Figure 15



Figure 16

TLV277x, TLV277xA
FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION
AND PHASE MARGIN**

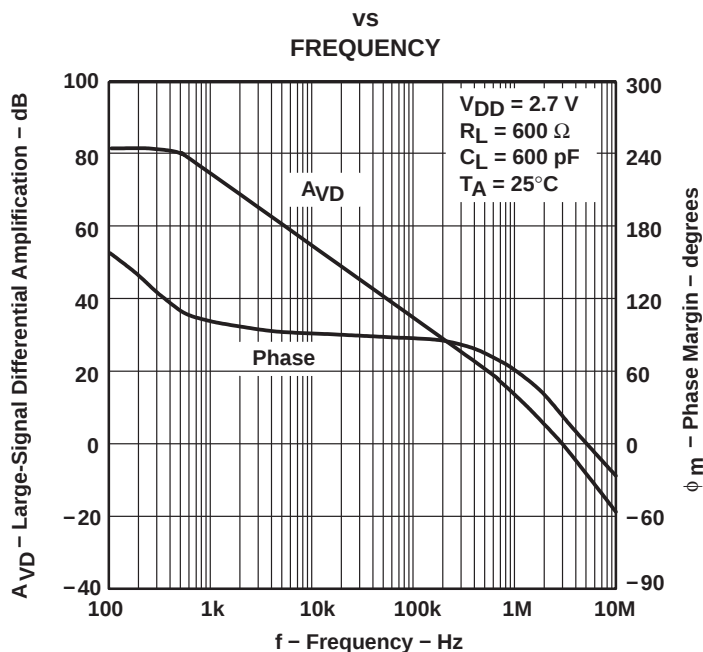


Figure 17

**LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION
AND PHASE MARGIN**

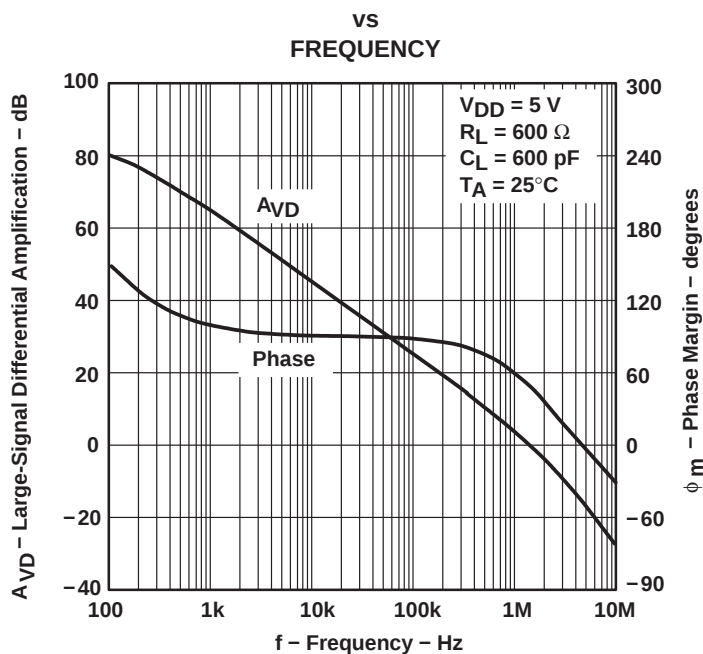


Figure 18

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

DIFFERENTIAL VOLTAGE AMPLIFICATION
vs
LOAD RESISTANCE



Figure 19

DIFFERENTIAL VOLTAGE AMPLIFICATION
vs
FREE-AIR TEMPERATURE



Figure 20

DIFFERENTIAL VOLTAGE AMPLIFICATION
vs
FREE-AIR TEMPERATURE



Figure 21

OUTPUT IMPEDANCE
vs
FREQUENCY

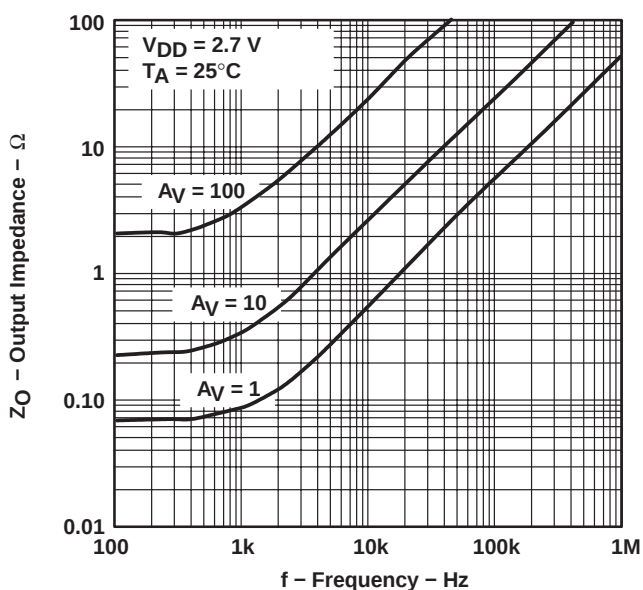


Figure 22

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 23



Figure 24



Figure 25



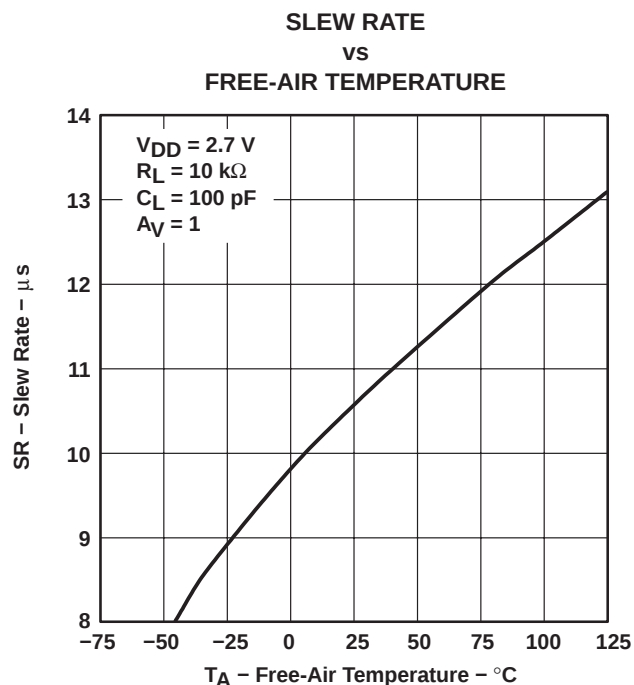
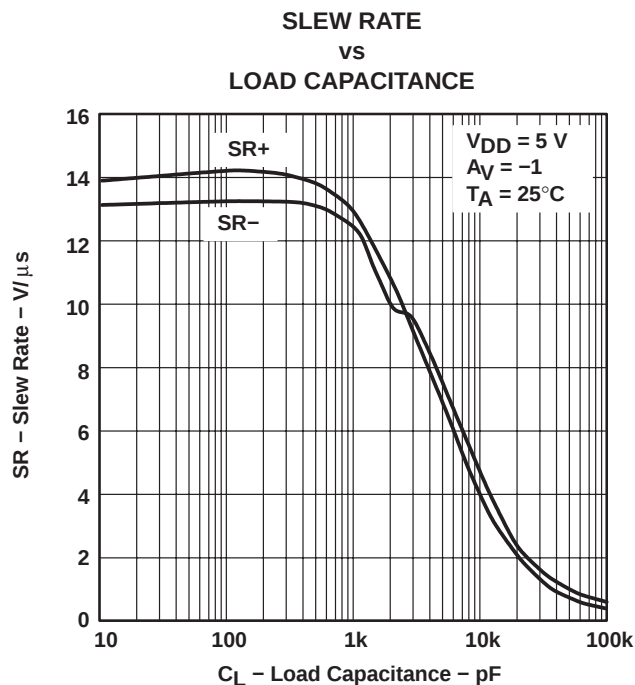
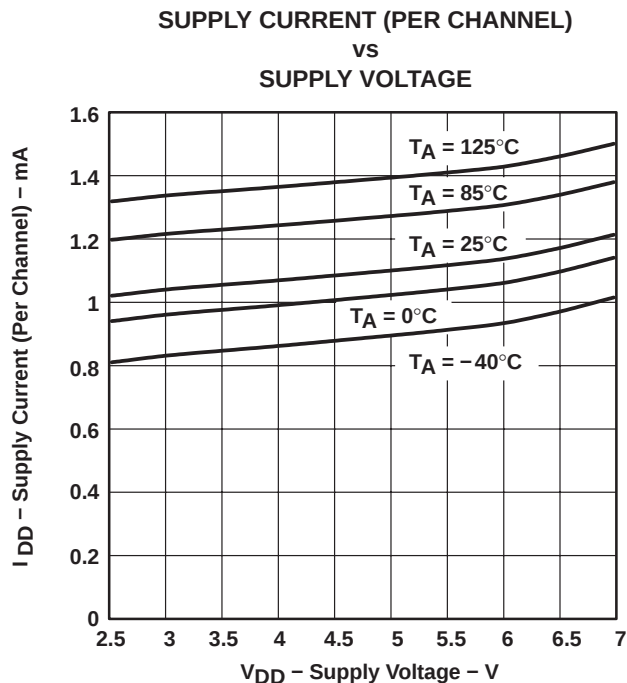
Figure 26

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



TLV277x, TLV277xA FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

VOLTAGE-FOLLOWER
SMALL-SIGNAL PULSE RESPONSE



Figure 31

VOLTAGE-FOLLOWER
SMALL-SIGNAL PULSE RESPONSE

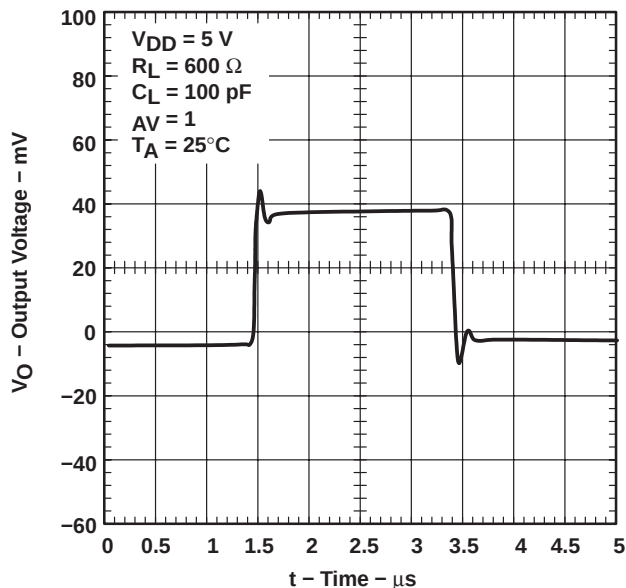


Figure 32

VOLTAGE-FOLLOWER
LARGE-SIGNAL PULSE RESPONSE



Figure 33

VOLTAGE-FOLLOWER
LARGE-SIGNAL PULSE RESPONSE



Figure 34

TLV277x, TLV277xA

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TYPICAL CHARACTERISTICS

INVERTING SMALL-SIGNAL PULSE RESPONSE



Figure 35

INVERTING SMALL-SIGNAL PULSE RESPONSE



Figure 36

INVERTING LARGE-SIGNAL PULSE RESPONSE



Figure 37

INVERTING LARGE-SIGNAL PULSE RESPONSE

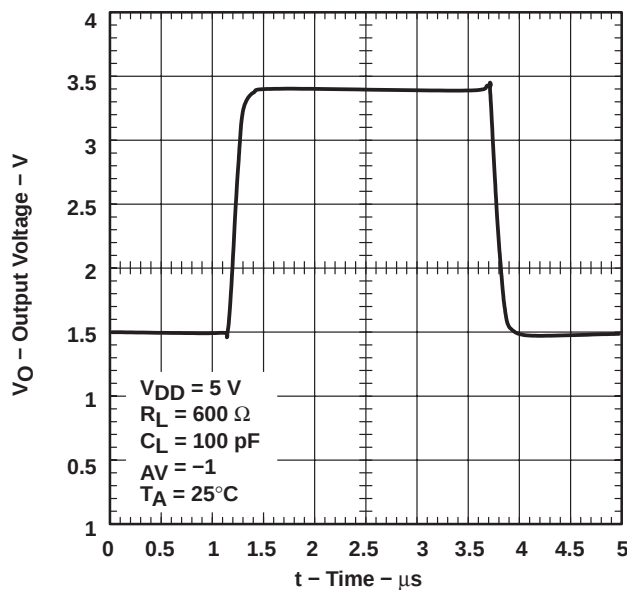


Figure 38

TLV277x, TLV277xA
FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

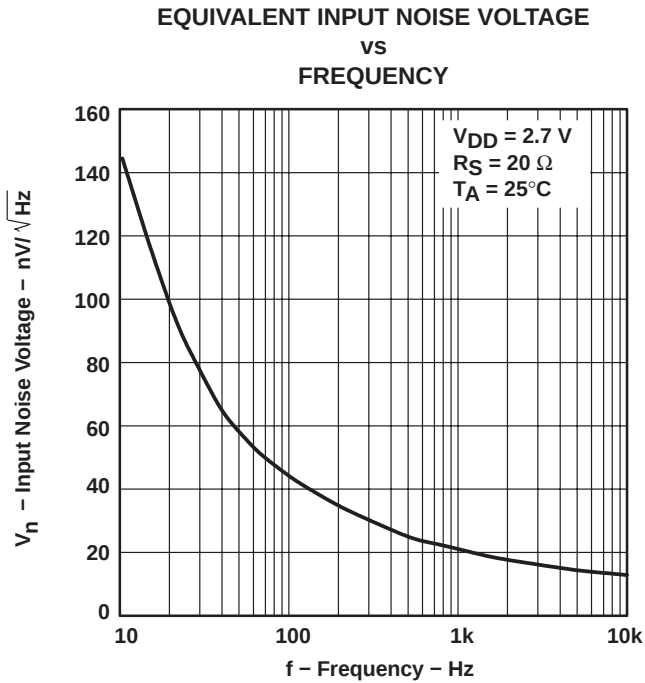


Figure 39



Figure 40



Figure 41

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 42



Figure 43



Figure 44



Figure 45

TLV277x, TLV277xA FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

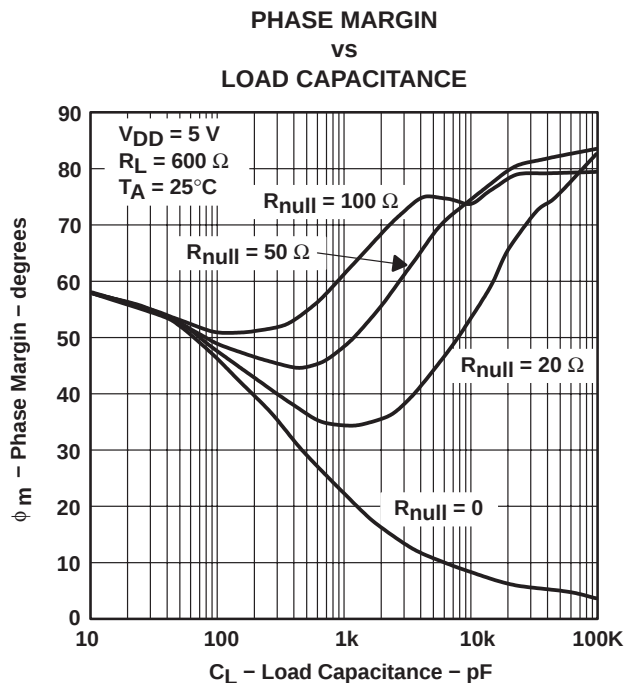


Figure 46

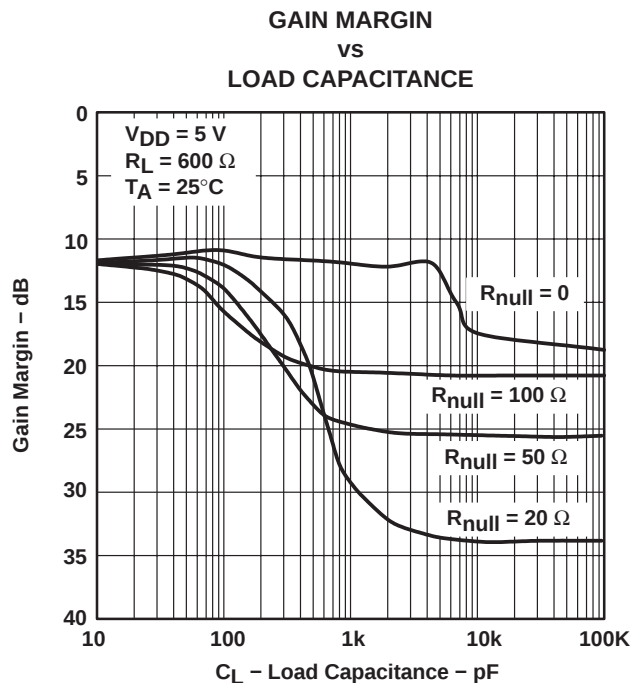


Figure 47

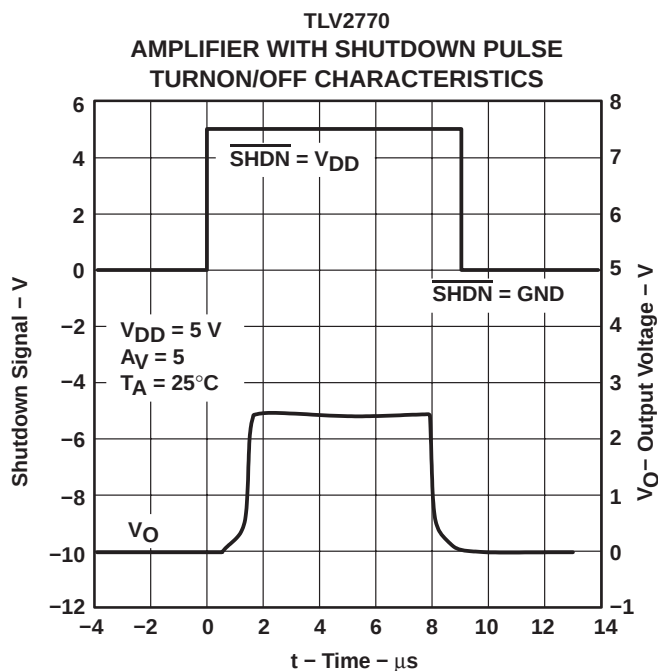


Figure 48

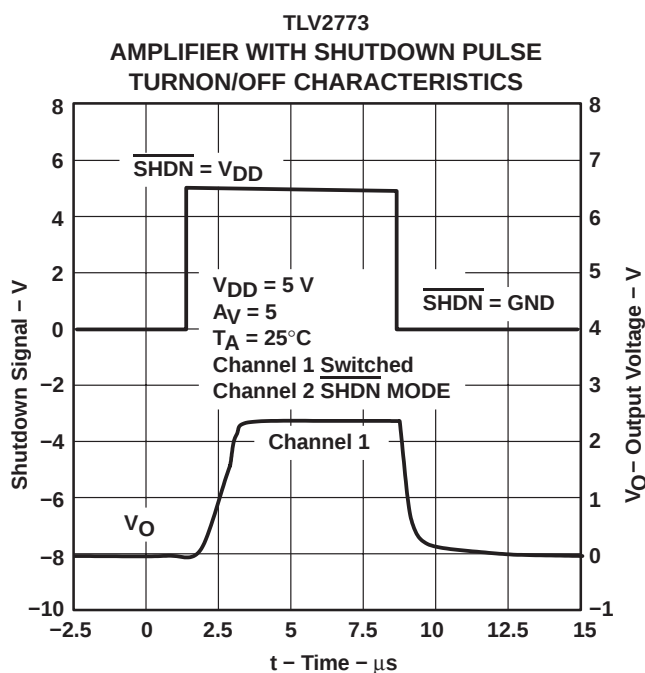


Figure 49

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 50



Figure 51



Figure 52



Figure 53

TLV277x, TLV277xA

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TYPICAL CHARACTERISTICS



Figure 54



Figure 55



Figure 56

TLV277x, TLV277xA

FAMILY OF 2.7-V HIGH-SLEW-RATE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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PARAMETER MEASUREMENT INFORMATION

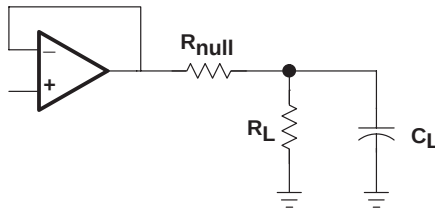


Figure 57

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 58. A minimum value of 20 Ω should work well for most applications.

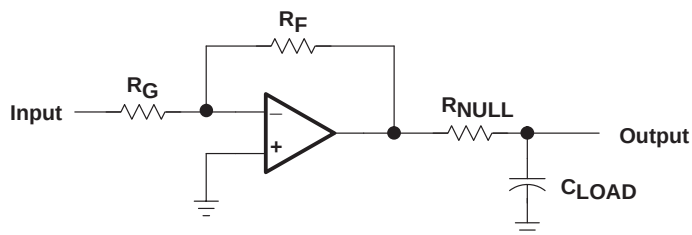


Figure 58. Driving a Capacitive Load

APPLICATION INFORMATION

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:



Figure 59. Output Offset Voltage Model

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 60).



Figure 60. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.



Figure 61. 2-Pole Low-Pass Sallen-Key Filter

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APPLICATION INFORMATION

using the TLV2772 as an accelerometer interface

The schematic, shown in Figure 62, shows the ACH04-08-05 interfaced to the TLV1544 10-bit analog-to-digital converter (ADC).

The ACH04-08-05 is a shock sensor designed to convert mechanical acceleration into electrical signals. The sensor contains three piezoelectric sensing elements oriented to simultaneously measure acceleration in three orthogonal, linear axes (x, y, z). The operating frequency is 0.5 Hz to 5 kHz. The output is buffered with an internal JFET and has a typical output voltage of 1.80 mV/g for the x and y axis and 1.35 mV/g for the z axis.

Amplification and frequency shaping of the shock sensor output is done by the TLV2772 rail-to-rail operational amplifier. The TLV2772 is ideal for this application as it offers high input impedance, good slew rate, and excellent dc precision. The rail-to-rail output swing and high output drive are perfect for driving the analog input of the TLV1544 ADC.



Figure 62. Accelerometer Interface Schematic

The sensor signal must be amplified and frequency-shaped to provide a signal the ADC can properly convert into the digital domain. Figure 62 shows the topology used in this application for one axis of the sensor. This system is powered from a single 3-V supply. Configuring the TLV431 with a 2.2-kΩ resistor produces a reference voltage of 1.23 V. This voltage is used to bias the operational amplifier and the internal JFETs in the shock sensor.

APPLICATION INFORMATION

gain calculation

Since the TLV2772 is capable of rail-to-rail output using a 3-V supply, $V_O = 0$ (min) to 3 V (max). With no signal from the sensor, nominal V_O = reference voltage = 1.23 V. Therefore, the maximum negative swing from nominal is $0\text{ V} - 1.23\text{ V} = -1.23\text{ V}$ and the maximum positive swing is $3\text{ V} - 1.23\text{ V} = 1.77\text{ V}$. By modeling the shock sensor as a low impedance voltage source with output of 2.25 mV/g (max) in the x and y axis and 1.70 mV/g (max) in the z axis, the gain of the circuit is calculated by equation 1.

$$\text{Gain} = \frac{\text{Output Swing}}{\text{Sensor Signal} \times \text{Acceleration}} \quad (1)$$

To avoid saturation of the operational amplifier, the gain calculations are based on the maximum negative swing of -1.23 V and the maximum sensor output of 2.25 mV/g (x and y axis) and 1.70 mV/g (z axis).

$$\text{Gain (x, y)} = \frac{-1.23\text{ V}}{2.25\text{ mV/g} \times -50\text{ g}} = 10.9 \quad (2)$$

and

$$\text{Gain (z)} = \frac{-1.23\text{ V}}{1.70\text{ mV/g} \times -50\text{ g}} = 14.5 \quad (3)$$

By selecting $R_3 = 10\text{ k}\Omega$ and $R_4 = 100\text{ k}\Omega$, in the x and y channels, a gain of 11 is realized. By selecting $R_3 = 7.5\text{ k}\Omega$ and $R_4 = 100\text{ k}\Omega$, in the z channel, a gain of 14.3 is realized. The schematic shows the configuration for either the x- or y-axis.

bandwidth calculation

To calculate the component values for the frequency shaping characteristics of the signal conditioning circuit, 1 Hz and 500 Hz are selected as the minimum required 3-dB bandwidth.

To minimize the value of the input capacitor (C1) required to set the lower cutoff frequency requires a large value resistor for R2 is required. A 1-M Ω resistor is used in this example. To set the lower cutoff frequency, the required capacitor value for C1 is:

$$C1 = \frac{1}{2\pi f_{\text{LOW}} R_2} = 0.159\text{ }\mu\text{F} \quad (4)$$

Using a value of 0.22 μF , a more common value of capacitor, the lower cutoff frequency is 0.724 Hz.

To minimize the phase shift in the feedback loop caused by the input capacitance of the TLV2772, it is best to minimize the value of the feedback resistor R4. However, to reduce the required capacitance in the feedback loop a large value for R4 is required. Therefore, a compromise for the value of R4 must be made. In this circuit, a value of 100 k Ω has been selected. To set the upper cutoff frequency, the required capacitor value for C2 is:

$$C2 = \frac{1}{2\pi f_{\text{HIGH}} R_4} = 3.18\text{ }\mu\text{F} \quad (5)$$

Using a 2.2-nF capacitor, the upper cutoff frequency is 724 Hz.

R5 and C3 also cause the signal response to roll off. Therefore, it is beneficial to design this roll-off point to begin at the upper cutoff frequency. Assuming a value of 1 k Ω for R5, the value for C3 is calculated to be 0.22 μF .

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APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV277x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- Ground planes—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- Proper power supply decoupling—Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- Sockets—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- Short trace runs/compact part placements—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- Surface-mount passive components—Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.

APPLICATION INFORMATION

general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 63 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

P_D = Maximum power dissipation of TLV277x IC (watts)

T_{MAX} = Absolute maximum junction temperature (150°C)

T_A = Free-ambient air temperature (°C)

$\theta_{JA} = \theta_{JC} + \theta_{CA}$

θ_{JC} = Thermal coefficient from junction to case

θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 63. Maximum Power Dissipation vs Free-Air Temperature

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APPLICATION INFORMATION

shutdown function

Three members of the TLV277x family (TLV2770/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is tied low, the supply current is reduced to 0.8 $\mu\text{A}/\text{channel}$, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal can either be left floating or pulled high. When the shutdown terminal is left floating, care needs to be taken to ensure that parasitic leakage current at the shutdown terminal does not inadvertently place the operational amplifier into shutdown. The shutdown terminal threshold is always referenced to $V_{DD}/2$. Therefore, when operating the device with split supply voltages (e.g. $\pm 2.5\text{ V}$), the shutdown terminal needs to be pulled to V_{DD-} (not GND) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figures 48, 49, and 50. The amplifier is powered with a single 5-V supply and configured as a noninverting configuration with a gain of 5. The amplifier turnon and turnoff times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables. The *bump* on the rising edge of the TLV2770 output waveform is due to the start-up circuit on the bias generator. For the dual and quad (TLV2773/5), this *bump* is attributed to the bias generator's start-up circuit as well as the crosstalk between the other channel(s), which are in shutdown.

Figures 55 and 56 show the amplifier's forward and reverse isolation in shutdown. The operational amplifier is powered by $\pm 1.35\text{-V}$ supplies and configured as a voltage follower ($A_V = 1$). The isolation performance is plotted across frequency for both 0.1 V_{PP} and 2.7 V_{PP} input signals. During normal operation, the amplifier would not be able to handle a 2.7- V_{PP} input signal with a supply voltage of $\pm 1.35\text{ V}$ since it exceeds the common-mode input voltage range (V_{ICR}). However, this curve illustrates that the amplifier remains in shutdown even under a worst case scenario.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9858802QPA	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9858802QPA TLV2772AM
TLV2770AID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2770AI
TLV2770AID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2770AI
TLV2770AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2770AI
TLV2770AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2770AI
TLV2770CD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2770C
TLV2770CD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2770C
TLV2770CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2770C
TLV2770CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2770C
TLV2770CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2770C
TLV2770CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2770C
TLV2770IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABP
TLV2770IDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABP
TLV2770IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2770I
TLV2770IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2770I
TLV2770IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2770I
TLV2770IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2770I
TLV2771AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2771AI
TLV2771AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2771AI
TLV2771CD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2771C
TLV2771CD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2771C
TLV2771CDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	VAMC
TLV2771CDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	VAMC
TLV2771CDBVT	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	0 to 70	VAMC
TLV2771CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2771C
TLV2771CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2771C
TLV2771ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2771I
TLV2771ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2771I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2771IDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	VAMI
TLV2771IDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VAMI
TLV2771IDBVT	Obsolete	Production	SOT-23 (DBV) 5	-	-	Call TI	Call TI	-40 to 125	VAMI
TLV2771IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2771I
TLV2771IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2771I
TLV2772AID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	2772AI
TLV2772AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772AI
TLV2772AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772AI
TLV2772AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2772AI
TLV2772AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2772AI
TLV2772AMD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-55 to 125	2772AM
TLV2772AMJGB	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9858802QPA TLV2772AM
TLV2772AMJGB.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9858802QPA TLV2772AM
TLV2772AQPW	Active	Production	TSSOP (PW) 8	150 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772AQ
TLV2772AQPW.A	Active	Production	TSSOP (PW) 8	150 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772AQ
TLV2772CD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	2772C
TLV2772CDGK	Obsolete	Production	VSSOP (DGK) 8	-	-	Call TI	Call TI	0 to 70	AAF
TLV2772CDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	AAF
TLV2772CDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	AAF
TLV2772CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2772C
TLV2772CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2772C
TLV2772CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2772C
TLV2772CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2772C
TLV2772ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 125	2772I
TLV2772IDGK	Obsolete	Production	VSSOP (DGK) 8	-	-	Call TI	Call TI	-40 to 125	AAG
TLV2772IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AAG
TLV2772IDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AAG
TLV2772IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772I
TLV2772IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2772IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2772IP
TLV2772IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2772IP
TLV2772MD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-55 to 125	2772M
TLV2772QD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772Q
TLV2772QD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772Q
TLV2772QPW	Obsolete	Production	TSSOP (PW) 8	-	-	Call TI	Call TI	-40 to 125	2772Q
TLV2772QPWR	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772Q
TLV2772QPWR.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2772Q
TLV2772QPWRG4	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU NIPDAU	Level-1-260C-UNLIM	-	2772Q
TLV2772QPWRG4.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	2772Q
TLV2773AIN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2773AI
TLV2773AIN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2773AI
TLV2773CDGS	Active	Production	VSSOP (DGS) 10	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABQ
TLV2773CDGS.A	Active	Production	VSSOP (DGS) 10	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABQ
TLV2773CDGSG4	Active	Production	VSSOP (DGS) 10	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABQ
TLV2773IDGSR	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABR
TLV2773IDGSR.A	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABR
TLV2774AID	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 125	TLV2774A
TLV2774AIDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2774A
TLV2774AIDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2774A
TLV2774AIN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2774A
TLV2774AIN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2774A
TLV2774AIPW	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-40 to 125	TY2774A
TLV2774CD	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	0 to 70	TLV2774C
TLV2774CDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2774C
TLV2774CDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2774C
TLV2774CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2774C
TLV2774CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2774C
TLV2774CPW	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	0 to 70	2774C
TLV2774CPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2774
TLV2774CPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2774

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2774ID	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 125	TLV2774I
TLV2774IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(TLV2774I, TLV277I)
TLV2774IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	(TLV2774I, TLV277I)
TLV2774IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2774I
TLV2774IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2774I
TLV2774IPW	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-40 to 125	TY2774
TLV2774IPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2774
TLV2774IPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2774
TLV2775AIN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2775A
TLV2775AIN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2775A
TLV2775AIPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-40 to 125	2775AI
TLV2775ID	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2775I
TLV2775ID.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2775I
TLV2775IDR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2775I
TLV2775IDR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2775I
TLV2775IPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2775I
TLV2775IPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2775I

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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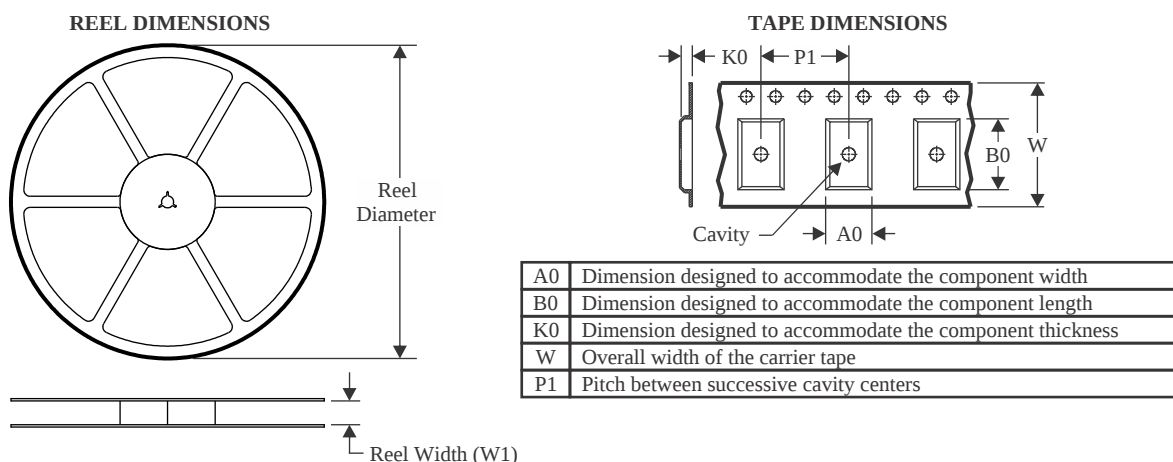
OTHER QUALIFIED VERSIONS OF TLV2771, TLV2772, TLV2772A, TLV2772AM, TLV2774, TLV2774A :

- Catalog : [TLV2772A](#)
- Automotive : [TLV2771-Q1](#), [TLV2772-Q1](#), [TLV2772A-Q1](#), [TLV2772A-Q1](#)
- Enhanced Product : [TLV2772A-EP](#), [TLV2772A-EP](#), [TLV2774-EP](#), [TLV2774A-EP](#)
- Military : [TLV2772AM](#)

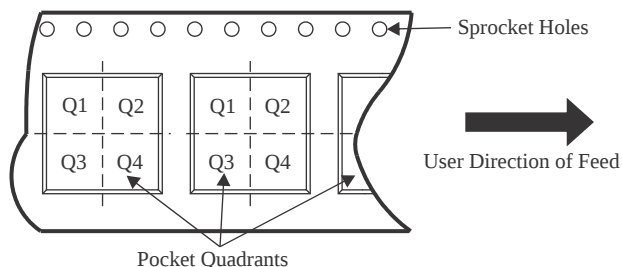
NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

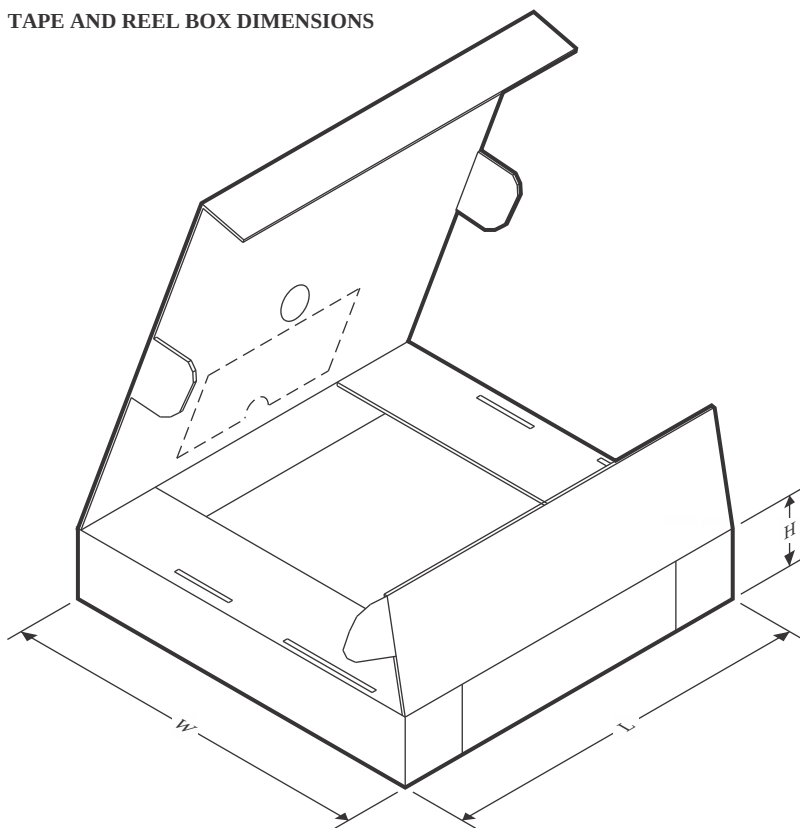


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2770CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2770IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2770IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2771AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2771CDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2771CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2771IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2771IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2772CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772IDGKR	VSSOP	DGK	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2772QPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2772QPWRG4	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TLV2773IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2774AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2774AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2774CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2774CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2774IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2774IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2775IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2775IPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

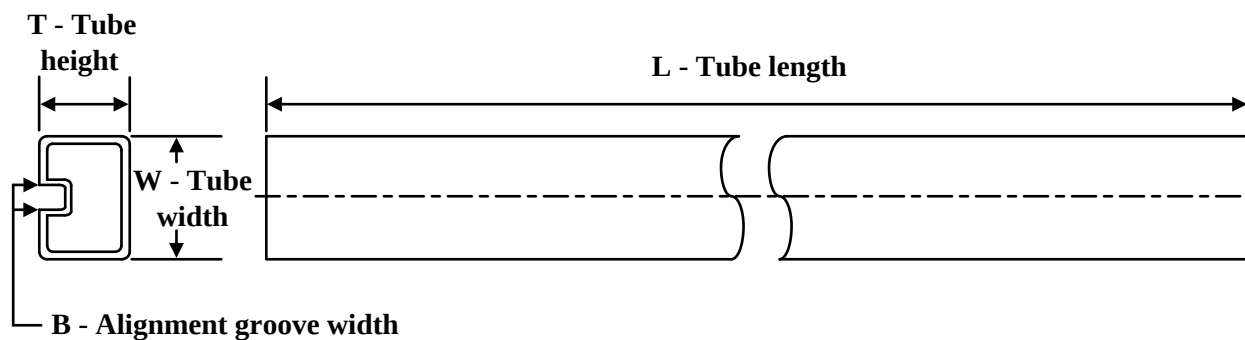
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2770CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2770IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2770IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2771AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2771CDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV2771CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2771IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV2771IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2772AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2772CDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
TLV2772CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2772CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2772IDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
TLV2772IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2772IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2772QPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
TLV2772QPWRG4	TSSOP	PW	8	2000	353.0	353.0	32.0
TLV2773IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2774AIDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2774AIDR	SOIC	D	14	2500	353.0	353.0	32.0
TLV2774CDR	SOIC	D	14	2500	353.0	353.0	32.0
TLV2774CPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2774IDR	SOIC	D	14	2500	353.0	353.0	32.0
TLV2774IPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2775IDR	SOIC	D	16	2500	350.0	350.0	43.0
TLV2775IPWR	TSSOP	PW	16	2000	353.0	353.0	32.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2770AID	D	SOIC	8	75	507	8	3940	4.32
TLV2770AID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2770AID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2770AID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2770AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2770AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2770CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2770CD	D	SOIC	8	75	507	8	3940	4.32
TLV2770CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2770CD.A	D	SOIC	8	75	507	8	3940	4.32
TLV2770CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2770CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2770IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2770IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2771CD	D	SOIC	8	75	507	8	3940	4.32
TLV2771CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2771CD.A	D	SOIC	8	75	507	8	3940	4.32
TLV2771CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2771ID	D	SOIC	8	75	507	8	3940	4.32
TLV2771ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2771ID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2771ID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2772AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2772AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2772AQPW	PW	TSSOP	8	150	530	10.2	3600	3.5
TLV2772AQPW.A	PW	TSSOP	8	150	530	10.2	3600	3.5
TLV2772CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2772CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2772IP	P	PDIP	8	50	506	13.97	11230	4.32

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2772IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2772QD	D	SOIC	8	75	507	8	3940	4.32
TLV2772QD.A	D	SOIC	8	75	507	8	3940	4.32
TLV2773AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2773AIN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2774AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2774AIN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2774CN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2774CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2774IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2774IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2775AIN	N	PDIP	16	25	506	13.97	11230	4.32
TLV2775AIN.A	N	PDIP	16	25	506	13.97	11230	4.32
TLV2775ID	D	SOIC	16	40	505.46	6.76	3810	4
TLV2775ID.A	D	SOIC	16	40	505.46	6.76	3810	4

D0014A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

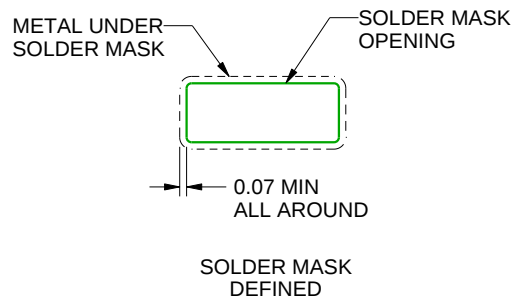
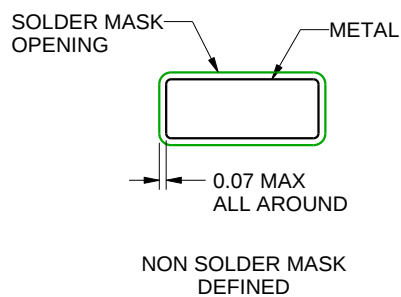
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

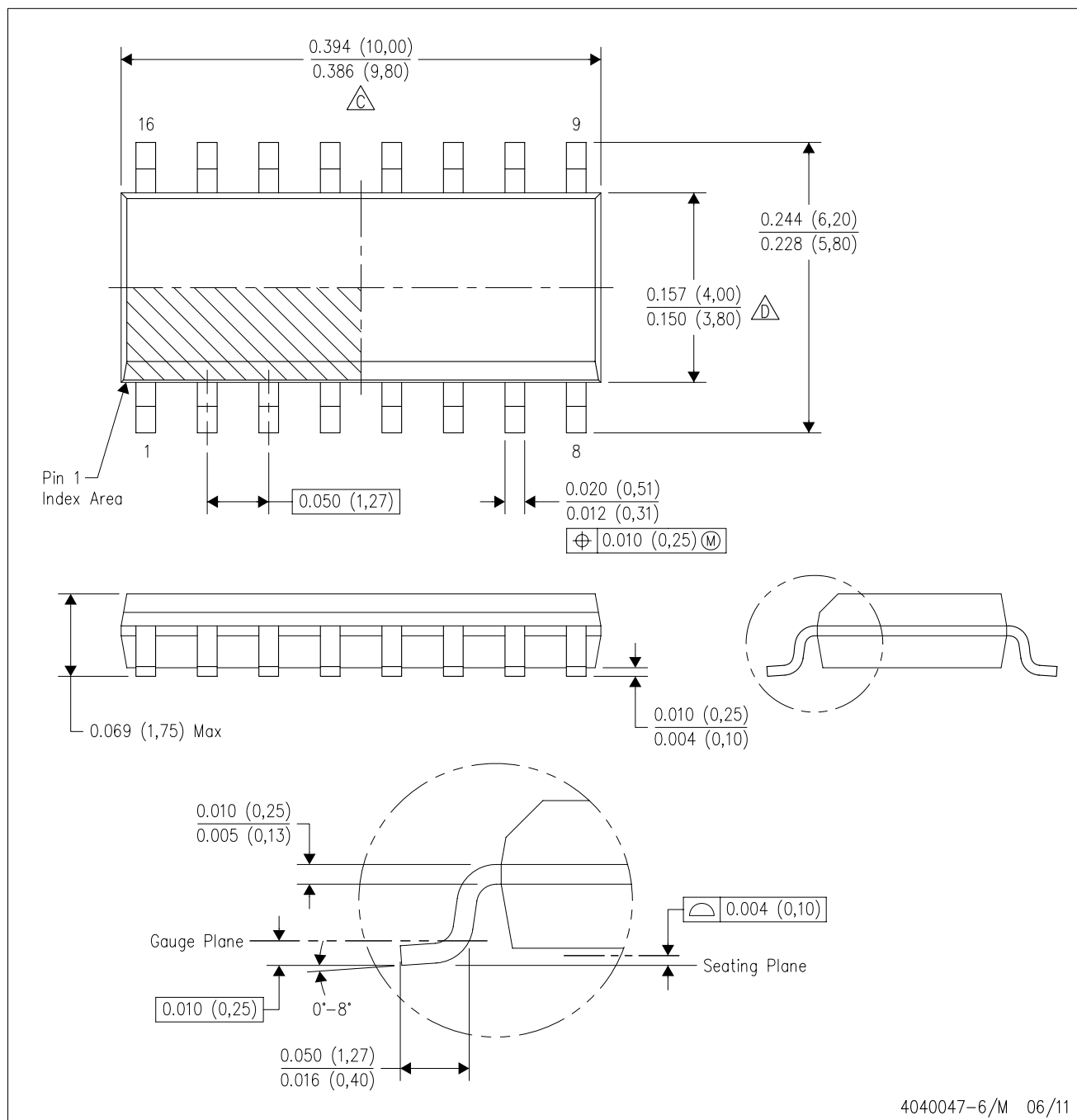
4220718/A 09/2016

NOTES: (continued)

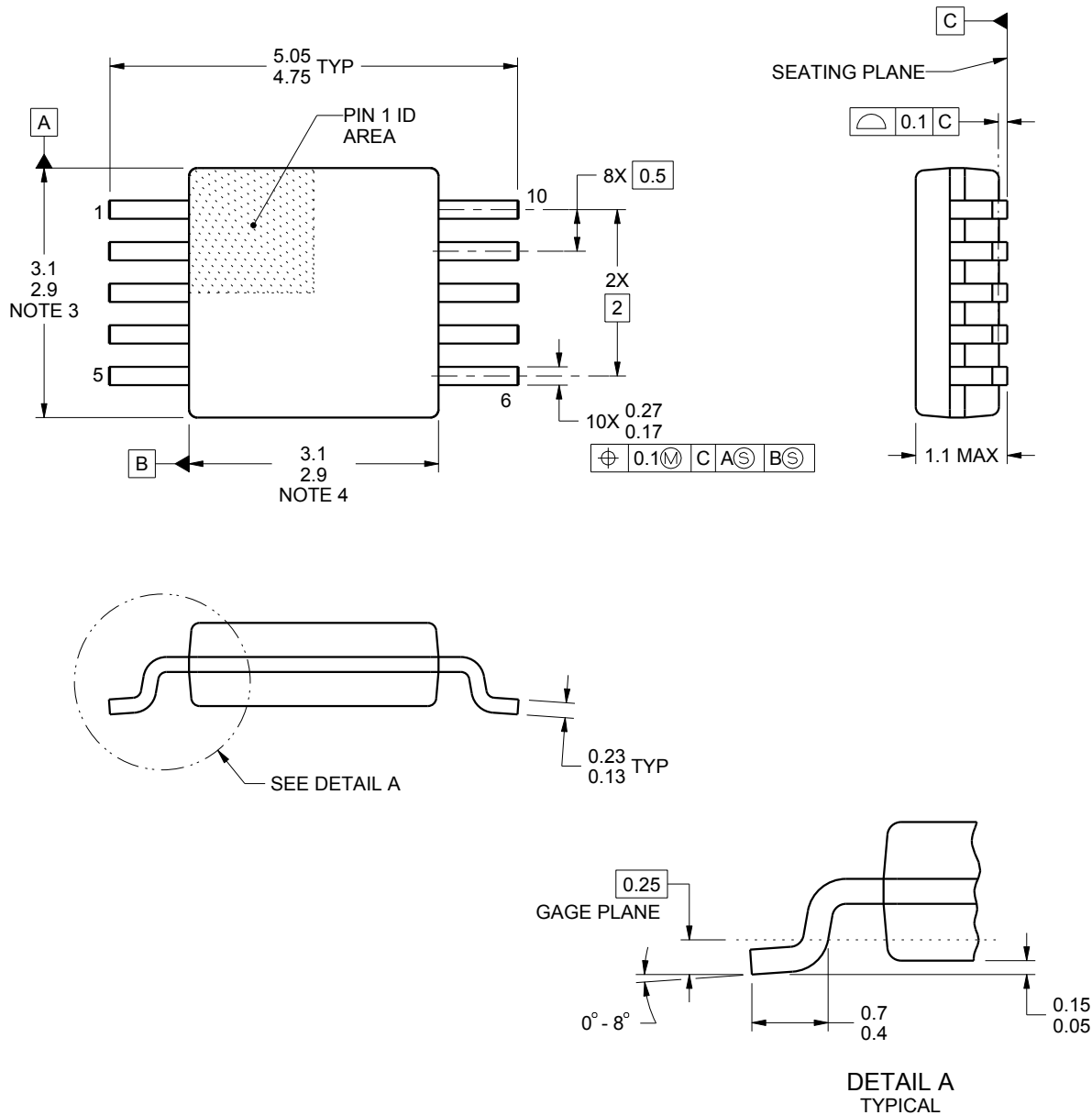
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - $\triangle C$ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - $\triangle D$ Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.



4221984/A 05/2015

NOTES:

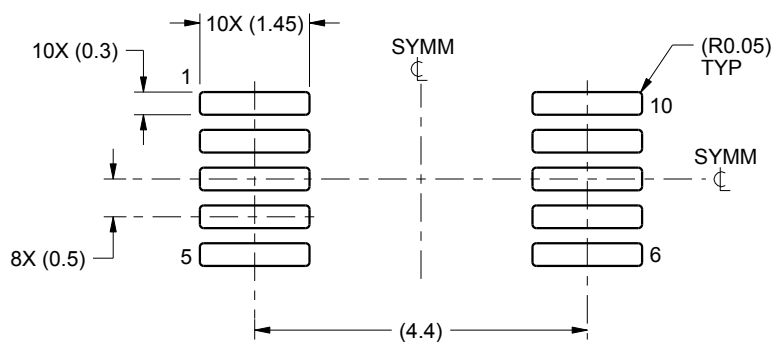
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

EXAMPLE BOARD LAYOUT

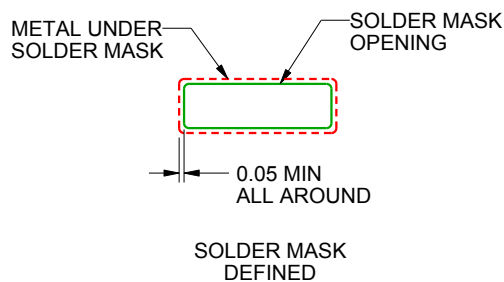
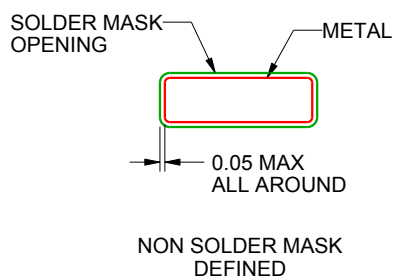
DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

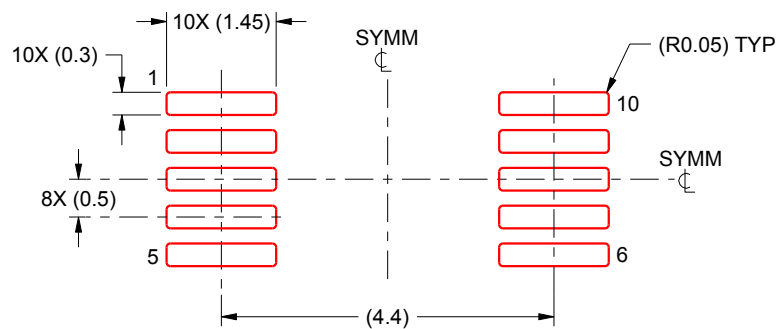
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

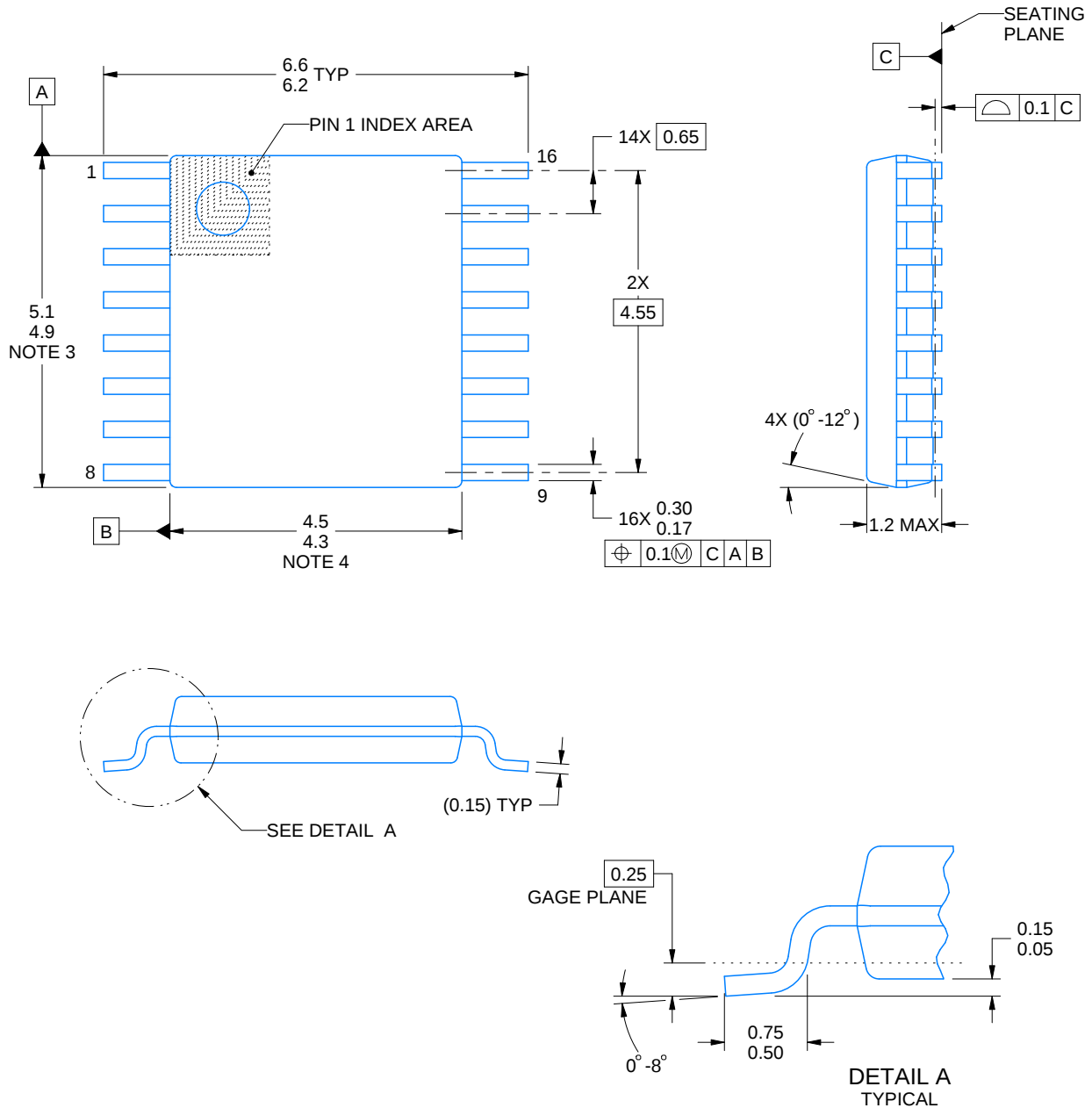
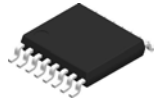


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



4220204/B 12/2023

NOTES:

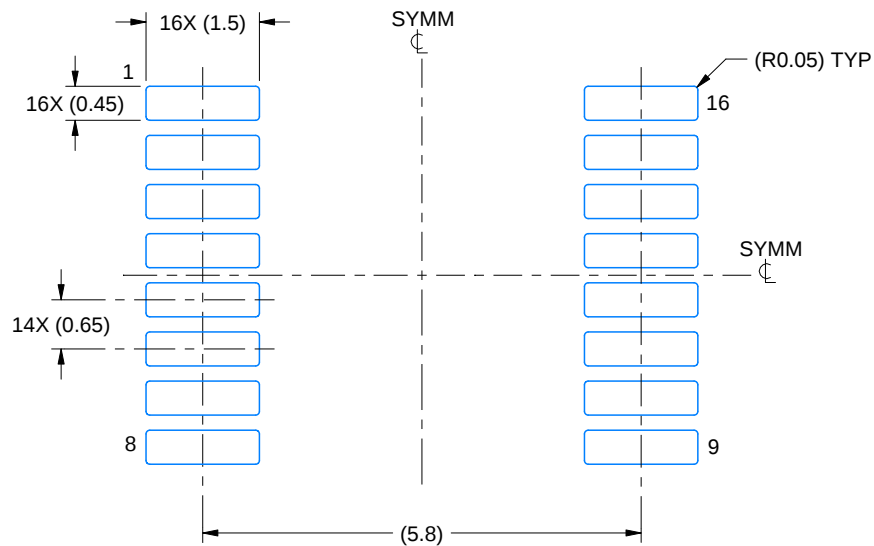
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

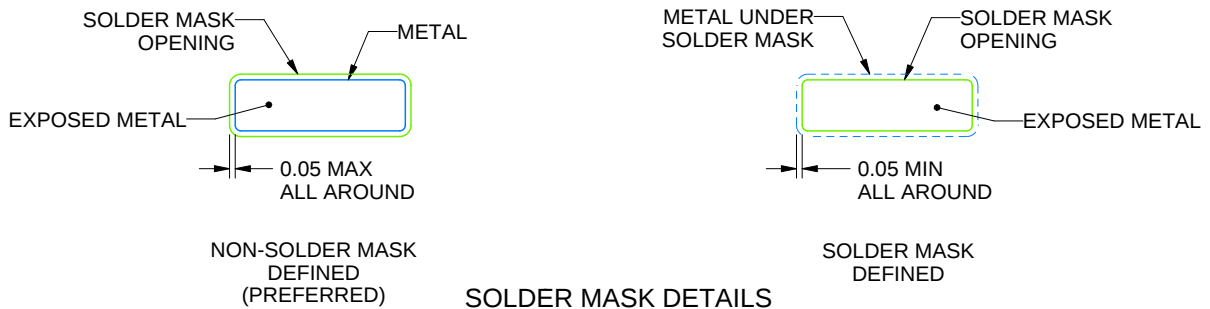
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

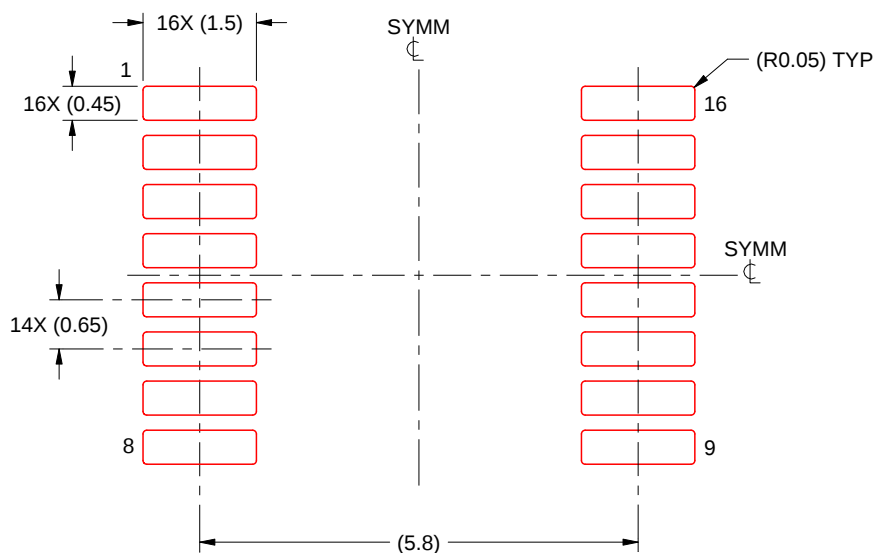
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

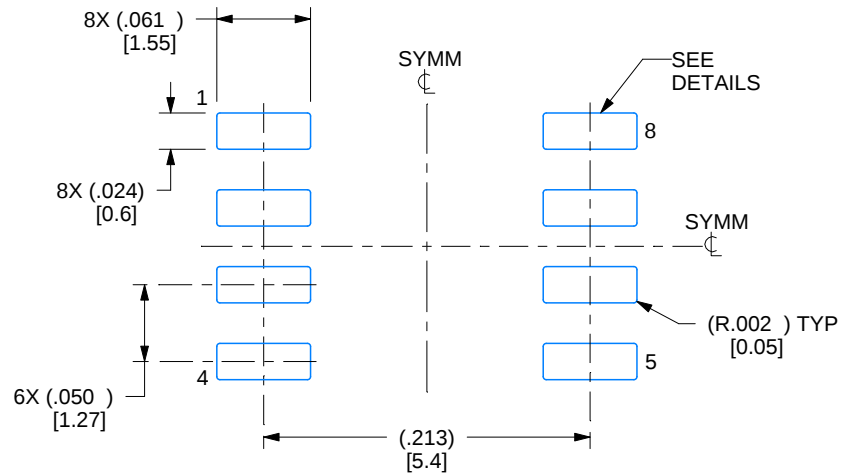


1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

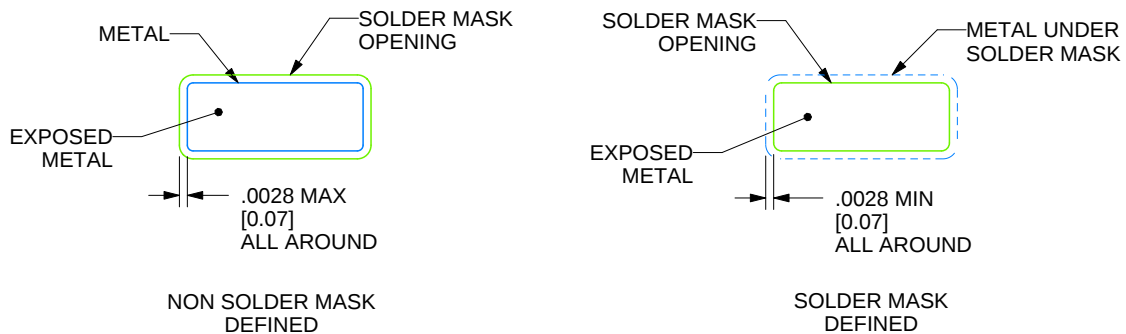
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

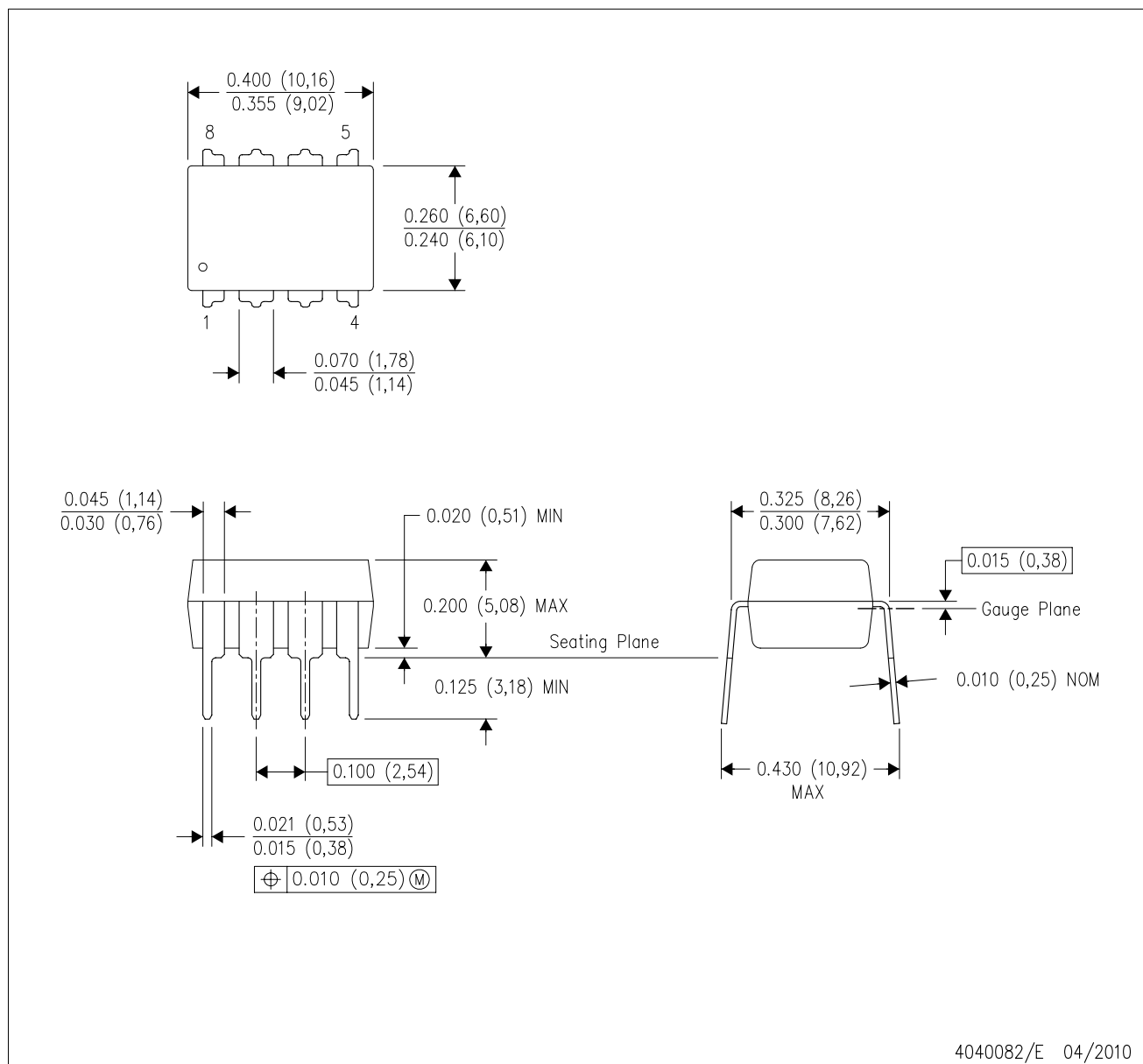
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

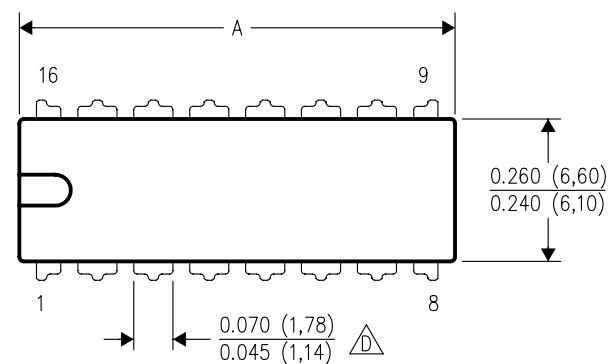


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

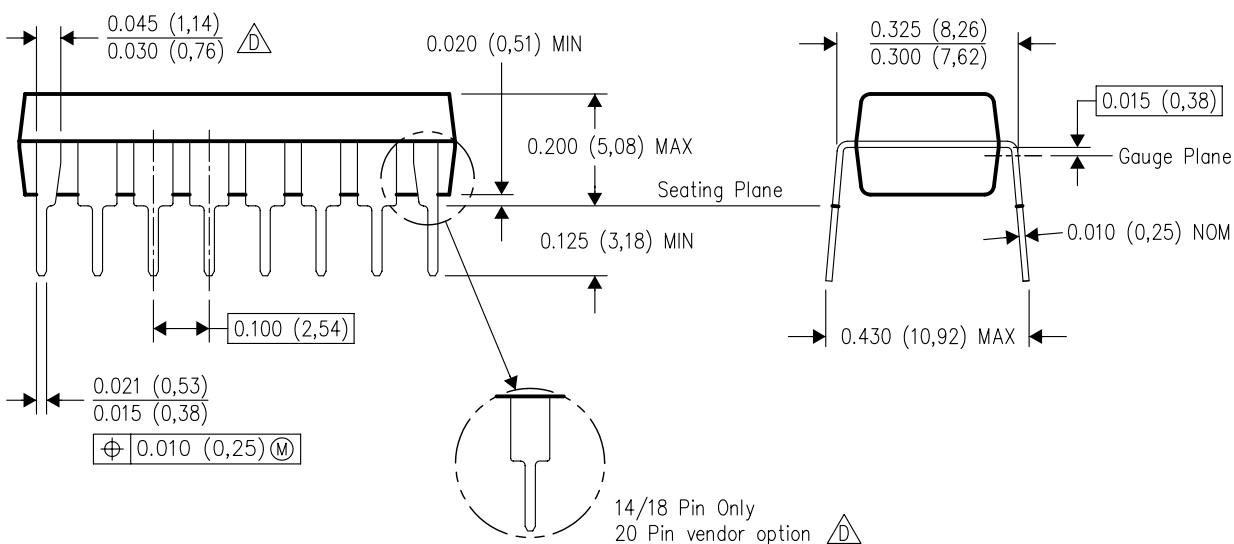
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



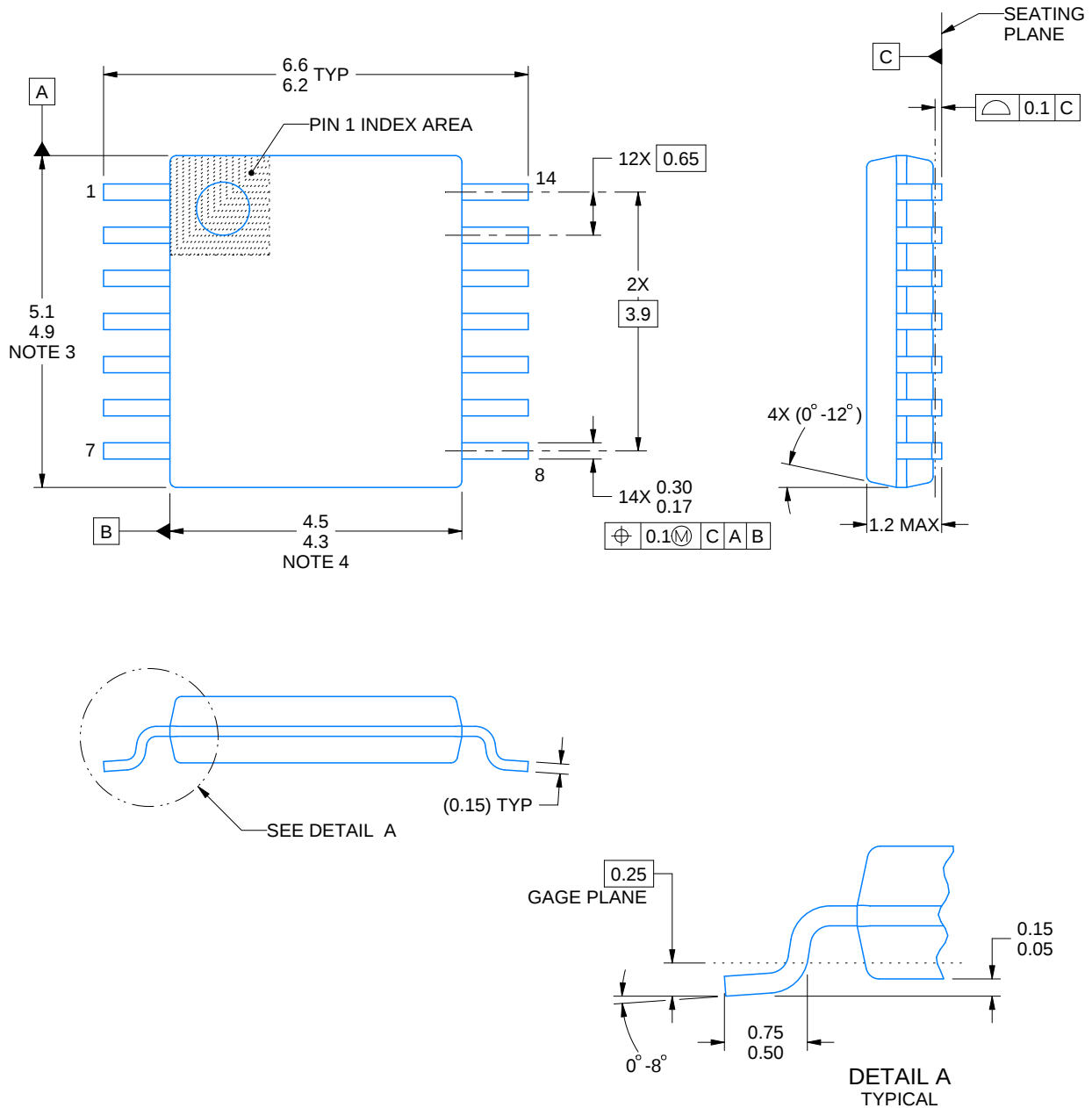
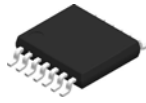
PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.



4220202/B 12/2023

NOTES:

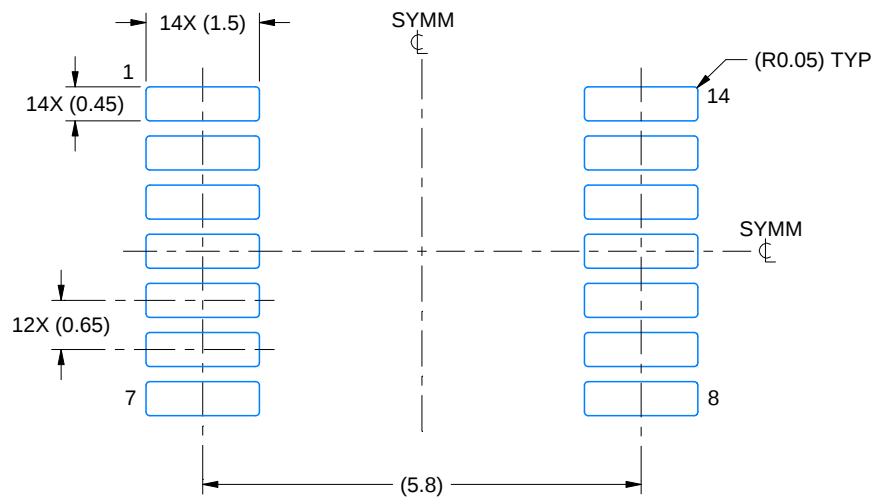
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

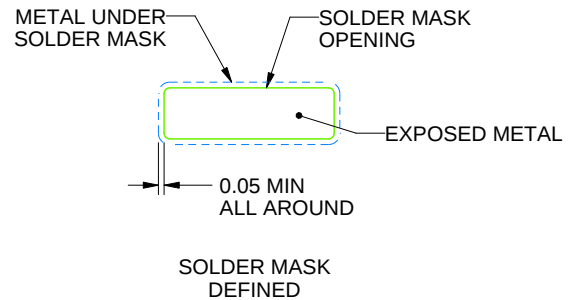
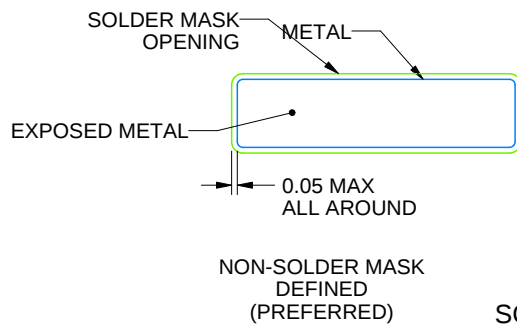
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

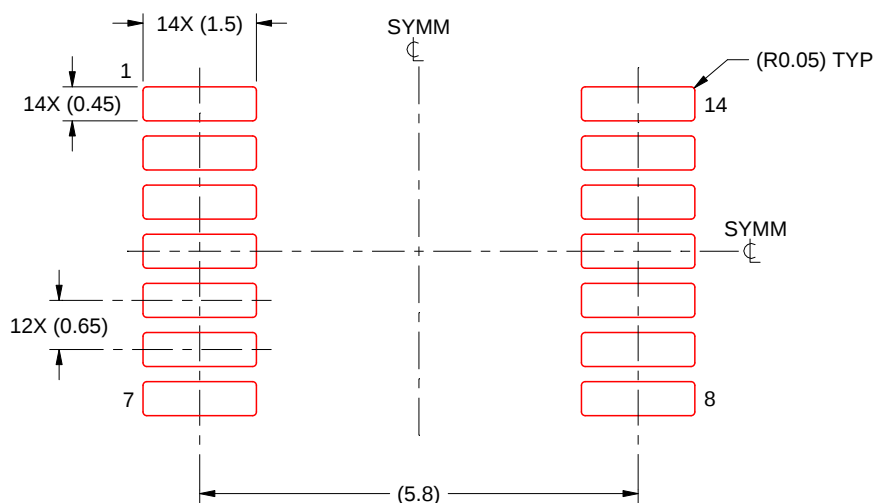
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

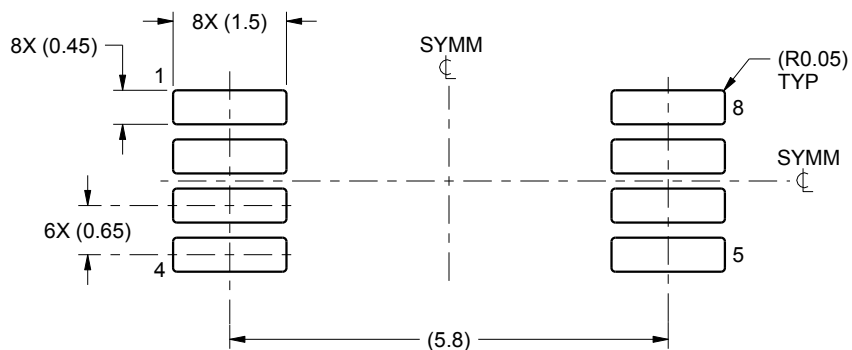
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

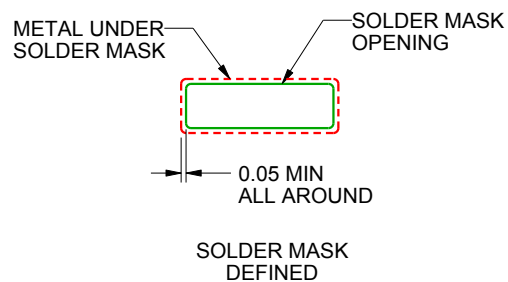
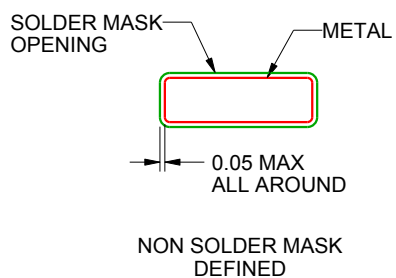
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

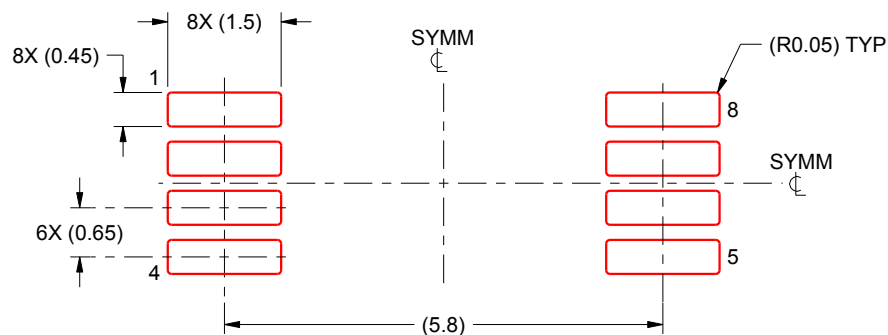
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

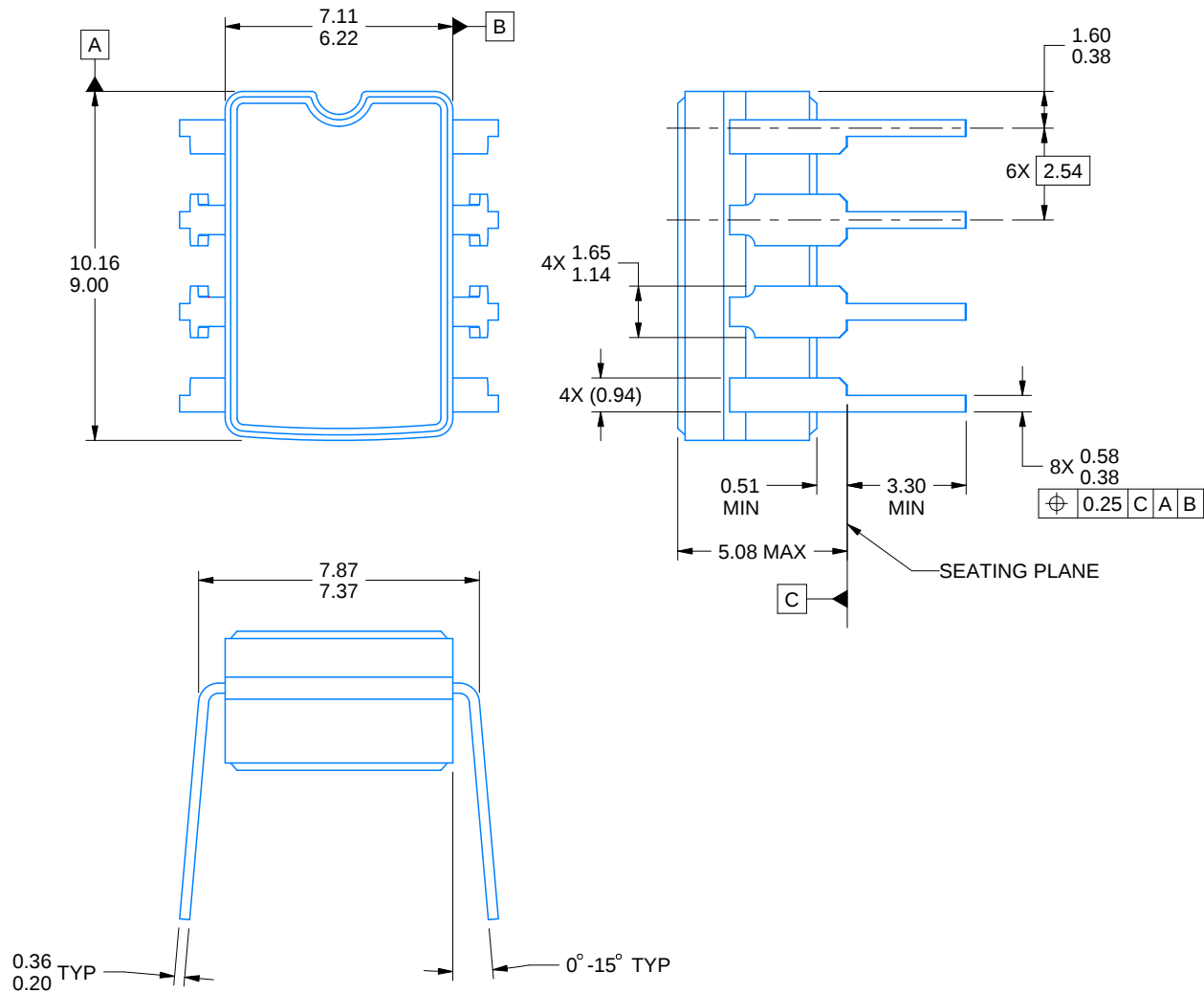
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

JG0008A

PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



4230036/A 09/2023

NOTES:

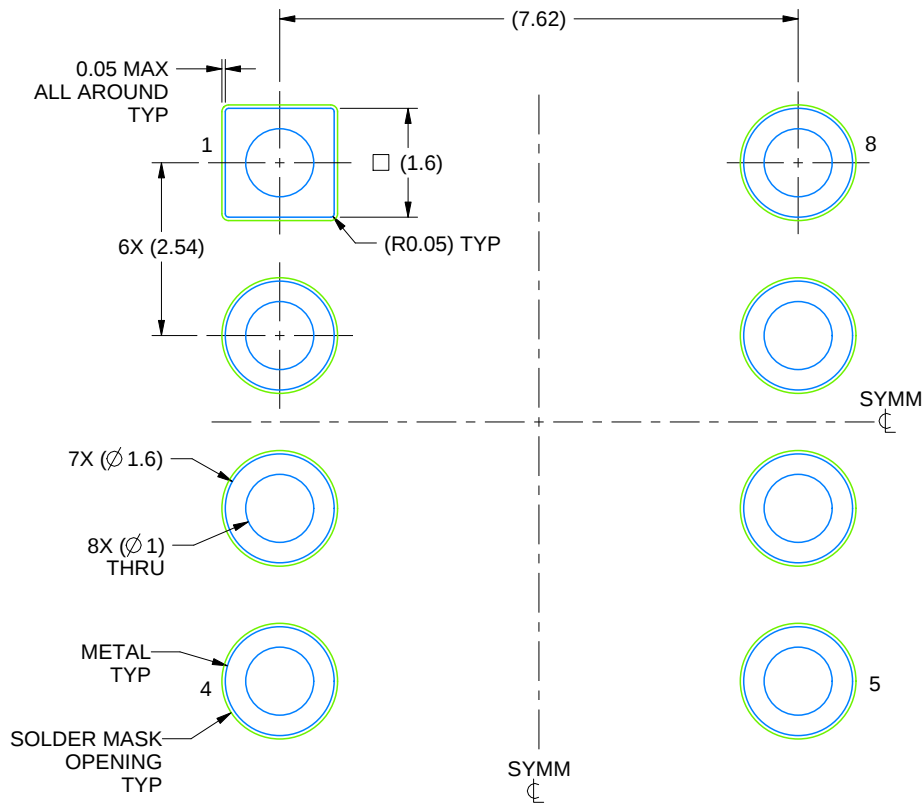
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

EXAMPLE BOARD LAYOUT

JG0008A

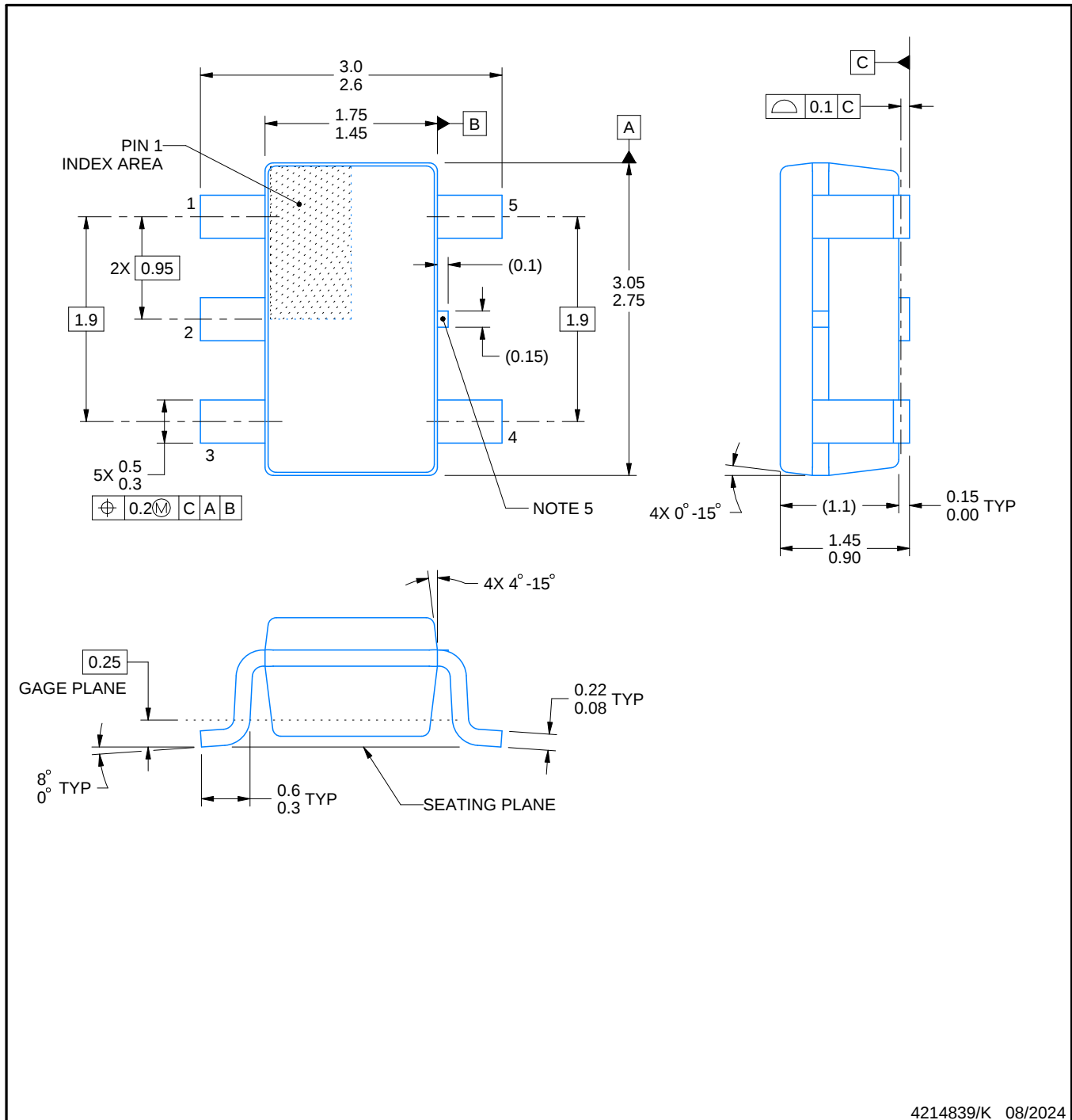
CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



LAND PATTERN EXAMPLE
NON SOLDER MASK DEFINED
SCALE: 9X

4230036/A 09/2023



NOTES:

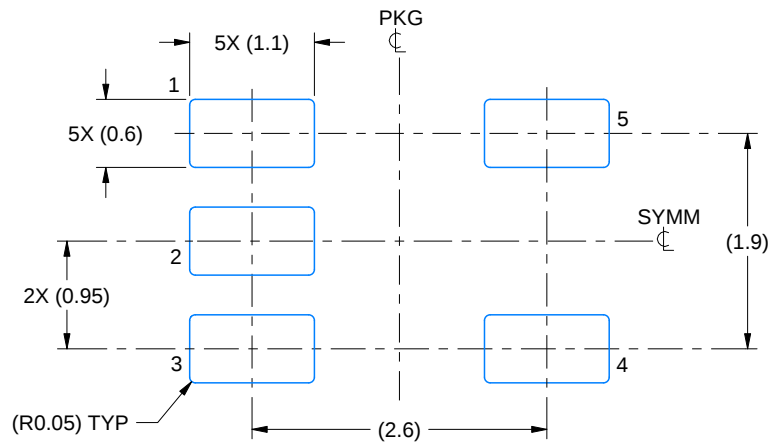
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

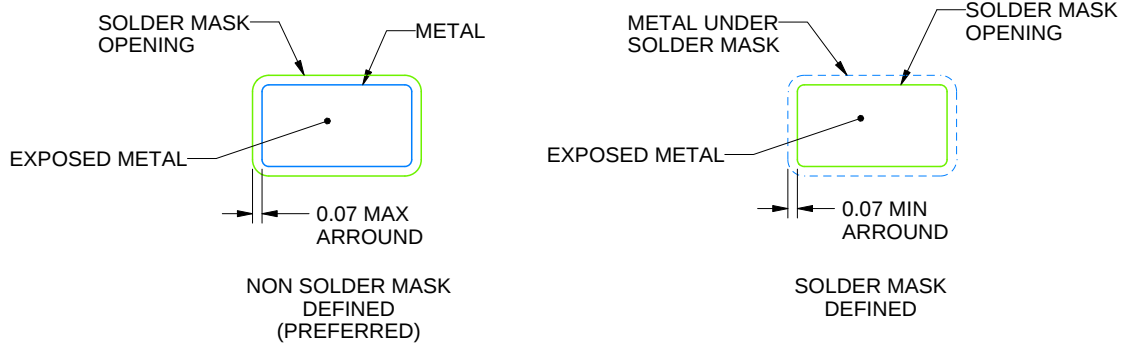
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

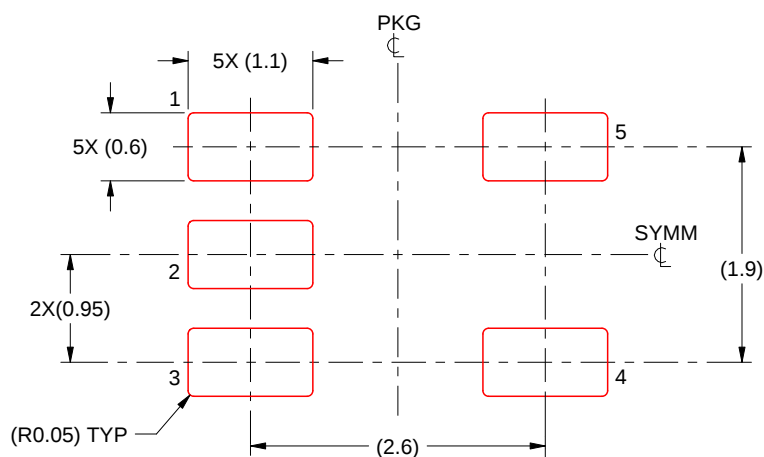
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



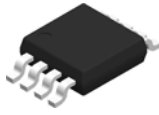
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

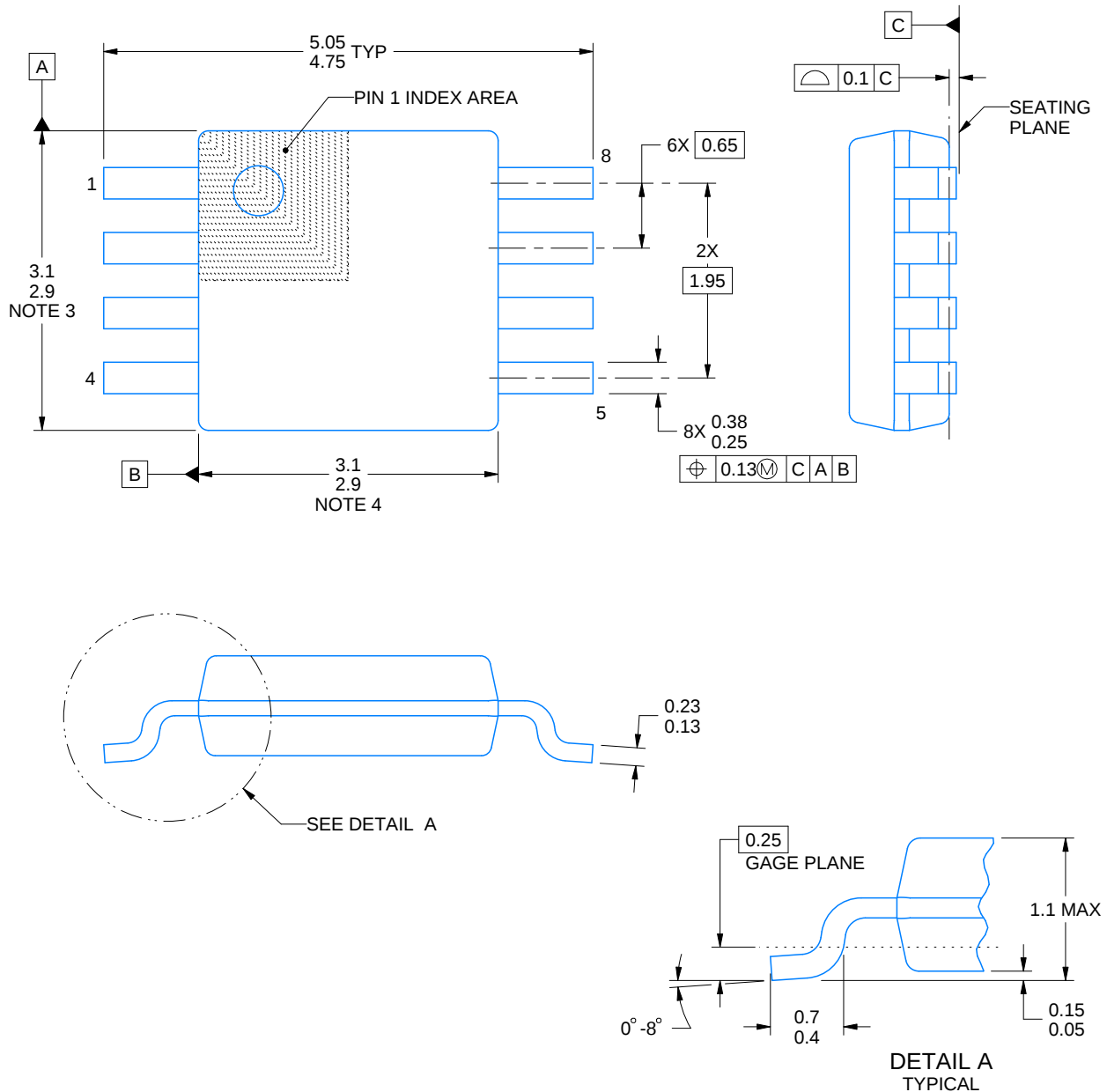
DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

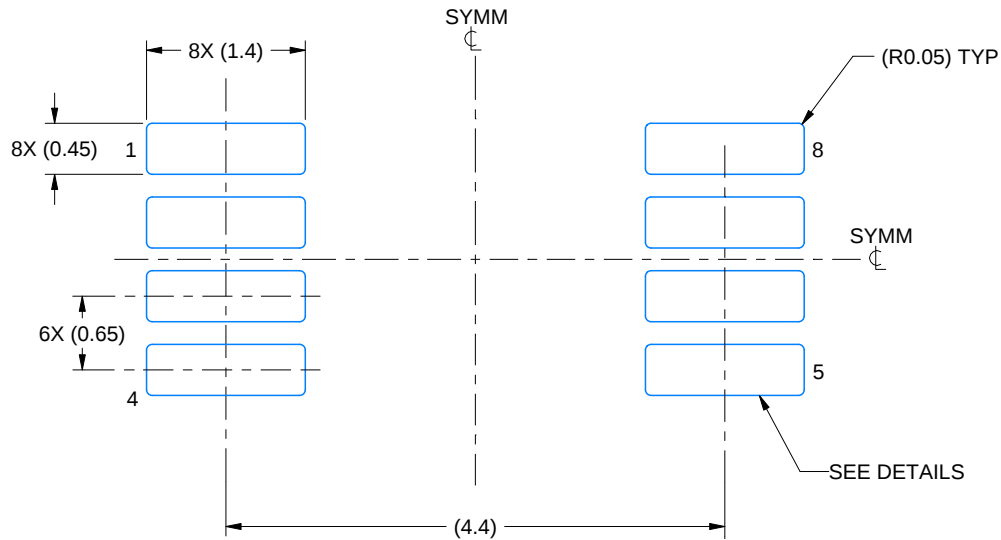
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

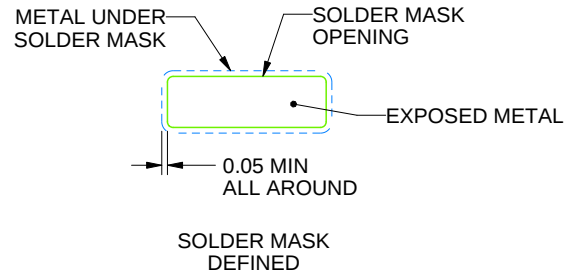
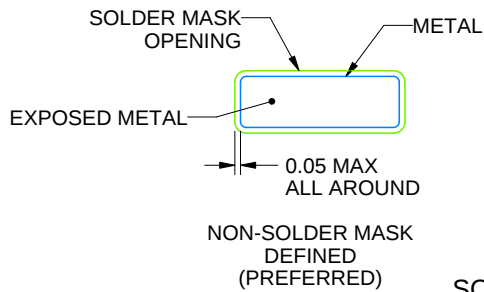
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

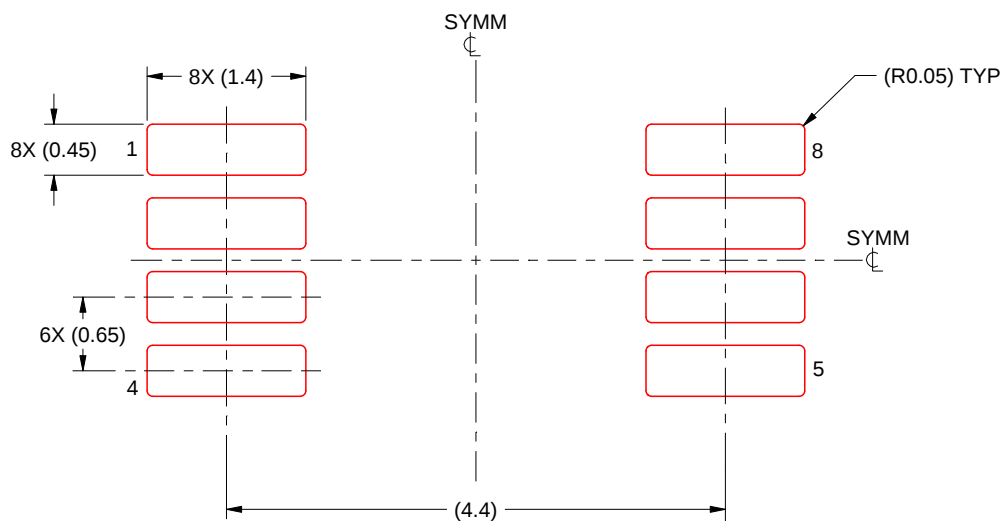
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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